Impact on backpropagation of the spatial heterogeneity of sodium channel kinetics in the axon initial segment

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Abstract

In a variety of neurons, action potentials (APs) initiate at the proximal axon, within a region called the axon initial segment (AIS), which has a high density of voltage-gated sodium channels (Na_Vs) on its membrane. In pyramidal neurons, the proximal AIS has been reported to exhibit a higher proportion of Na_Vs with gating properties that are "*right-shift*ed" to more depolarized voltages, compared to the distal AIS. Further, recent experiments have revealed that as neurons develop, the spatial distribution of Na_V subtypes along the AIS can change substantially, suggesting that neurons tune their excitability by modifying said distribution. When neurons are stimulated axonally, computational modelling has shown that this spatial separation of gating properties in the AIS enhances the backpropagation of APs into the dendrites. In contrast, in the more natural scenario of somatic stimulation, our simulations show that the same distribution can impede backpropagation. We implemented a range of hypothetical Na_V distributions in the AIS of three multicompartmental pyramidal cell models and investigated the precise kinetic mechanisms underlying such effects, as the spatial distribution of Na_V subtypes is varied. With axonal stimulation, proximal Na_V *availability* dominates, such that concentrating *right-shift*ed Na_Vs in the proximal AIS promotes backpropagation. However, with somatic stimulation, the models are insensitive to *availability*. Instead, the higher *activation* threshold of *right-shift*ed Na_Vs in the AIS impedes backpropagation. Therefore, recently observed developmental changes to the spatial separation and relative proportions of $Na_V1.2$ and $Na_V1.6$ in the AIS differentially impact *activation* and *availability*. The effects on backpropagation, and potentially learning, are opposite for orthodromic versus antidromic stimulation.

Author Summary

Neurons use sodium ion currents, controlled by a neuron's voltage, to trigger signals called action potentials (APs). These APs typically result from synaptic input from other neurons onto the dendrites and soma. An AP is generated at the axon initial segment (AIS) just beyond the soma. From there, it travels down the axon to other cells, but can also propagate "backwards" towards the soma and dendrites. This "backpropagation" allows a comparison at synapses of the timing of outgoing and incoming signals, a feedback process that modifies synaptic connection strengths linked to learning. It is puzzling that in many neurons, sodium ion channels come in two types: high-voltage threshold channels clustered near the soma where the AIS begins, and low-voltage ones further away towards the axon. This separation changes in the early development of the animal, which raises the question of its role in backpropagation. We constructed a detailed mathematical model to explore how separation affects backpropagation. Separation either impedes or enhances learning, depending on whether the AP results from synaptic inputs or, less typically, currents moving backwards from the axon. This is explained by the different effects the separation has on two key kinetic processes that govern sodium currents.

1   Introduction

In fluorescence microscopy images of neurons, the axon initial segment (AIS) is visible as a patch of axonal membrane near the soma with a high density of voltage-gated ion channels. These channels enable the AIS to initiate and shape action potentials (spikes) and regulate neuronal excitability [1]. The AIS can be thought of as an organelle, that lives within the first $\approx 100\mu\text{m}$ of axonal membrane and whose function is to supply the current needed to initiate spikes when the neuron decides to fire —usually in response to synaptic input. The AIS can move, up and down the axon and also change its length on a timescale of hours to days. This phenomenon, called structural AIS plasticity, enables neurons to optimize their sensitivity to specific input frequencies during development and to homeostatically adjust their intrinsic excitability [2, 3, 4]. GABAergic input can also impinge on the AIS from axo-axonic synapses, such that the AIS can be modulated directly by interneurons. Synaptic input at the AIS can rapidly and precisely control the excitability of individual neurons for sound localization [5]. Fast AIS plasticity, including receptor-mediated changes to local ion channel properties and endocytosis of voltage-gated channels, occurs on timescales of seconds to minutes [6]. (This is distinct from pathological remodelling induced by ischemia, although in [7], it was recently demonstrated that cortical neurons are more robust to interruptions in blood flow than previously thought.) The outsized electrophysiological influence of the AIS demands robust characterization of this short piece of axon as it interacts with its environment.

Over three-quarters of all neurons in the mammalian cortex are pyramidal cells (see Figure S1), which have dendrites spanning the thickness of the cortex (several mm) and AIS lengths on the order of tens of μm [8, 9, 10]. The AIS requires a high density of voltage-gated sodium channels (Na_Vs) to prime and initiate action potentials [11, 12, 13]. In pyramidal cells, the AIS features two Na_V subtypes, with an interesting spatial distribution: $\text{Na}_\text{V}1.2$ channels cluster near the soma (i.e. at the proximal AIS) while $\text{Na}_\text{V}1.6$ cluster toward the distal AIS [14, 15, 16]. However, the purpose of this separated distribution of Na_V subtypes remains unclear [17, 18]. Further, recent experiments have revealed that as neurons develop, the spatial distribution of Na_Vs in the AIS can change substantially, suggesting that neurons tune their excitability by modifying said distribution [19].

It is a prevalent view that the Hodgkin-Huxley kinetics of $\text{Na}_\text{V}1.2$ are *right-shift*ed relative to those of $\text{Na}_\text{V}1.6$ by an amount $V_\text{RS} \sim 10 - 15\text{mV}$ [20, 14]. The separated Na_V distribution is reported to

⁷⁹ promote backpropagation —which is important for learning— following axonal stimulation [14]. There

⁸⁰ is also evidence that mutations which alter the gating properties of $Na_V1.2$ are involved in epilepsy and

⁸¹ autism [21]. Backpropagated spikes drive learning by depolarizing the postsynaptic membrane, which

⁸² triggers metabolic events that give rise to synaptic plasticity, including spike-timing-dependent plasticity

⁸³ [22]. There is experimental evidence that postsynaptic backpropagation can release retrograde messengers

⁸⁴ into the synapse, and influence the future release of neurotransmitters from the presynaptic neuron [23].

⁸⁵ A backpropagating action potential (BAP) can underlie bursting in cortical neurons as it can return

⁸⁶ to the cell body from the dendrites as a depolarizing after potential, which in turn can initiate another

⁸⁷ somatic AP [24, 25]. Bursting can also occur in layer 5 pyramidal cells following the generation of a

⁸⁸ dendritic BAP-activated Ca^{2+} spike (BAC spike), e.g. in the presence of synaptic input. The associated

⁸⁹ BAPs can further influence the dendritic dynamics [26, 27, 28, 29].

⁹⁰ Not all layer 5 pyramidal cells can generate dendritic spikes as the size of the apical dendritic tree varies

⁹¹ [30]. Dendritic spikes have also been reported to vary across species, and are not common in human layer 5

⁹² pyramidal cells [31], owing partly to their enhanced dendritic compartmentalization [32]. Thus, to validate

⁹³ and further understand the original reports that Na_V segregation promotes BAPs, we investigate how Na_V

⁹⁴ segregation in the AIS can promote BAPs using the model of [14] (itself based on [24]). This provides the

⁹⁵ backbone to study the basic effects on BAPs of the AIS excitability profile, under both somatic and axonal

⁹⁶ stimulation. For the sake of generality, we complement these results by considering a state-of-the-art model

⁹⁷ of layer 5 pyramidal cells with perisomatic BAPs and dendritic BAC firing [27], adapted to include a more

⁹⁸ realistic AIS and axon.

⁹⁹ Other computational powers are attributed to the AIS. Moving the initiation site away from the soma

¹⁰⁰ (i.e. toward the distal AIS) beyond a critical distance enables high-frequency spiking in cortical neurons,

¹⁰¹ increasing the maximum spike frequency by an order of magnitude [13]. Separating $Na_V1.6$ into the distal

¹⁰² AIS is said to push the initiation site toward that location, owing to those channels' lower voltage threshold

¹⁰³ [14, 20]. However, in [33], simulations having only one Na_V type demonstrated that passive cable properties

¹⁰⁴ are sufficient to locate AP initiation at the distal AIS.

¹⁰⁵ In our simulations, we alter the composition of the AIS and look for changes in the backpropagation

¹⁰⁶ threshold. The model neurons are allowed to distribute *right-shift*ed Na_V gating properties along the

¹⁰⁷ AIS, by differentially distributing two functionally distinct classes of sodium channels, referred to here

as $Na_V1.2$ and $Na_V1.6$ following [14], [20] and [19]. Our modelling study is motivated by the following

question: what effect does the separated spatial distribution of $Na_V1.2$ (or *right-shift*ed gating properties)

and $Na_V1.6$ (*left-shift*) in the AIS have on excitability and backpropagation? In particular, how does the

finding in [14], that the separated distribution of Na_V subtypes favours backpropagation, generalize to the

more common situation of somatic stimulation?

A natural approach is to systematically alter that Na_V distribution, by varying the extent to which

Na_V subtypes are spatially segregated in the AIS without affecting the total Na_V density. We compute the

threshold for backpropagation as the amplitude of a brief current pulse that causes an AP to propagate back

into the dendrites and cause a sufficient depolarization (Section S1.2, Section S1.3). This is done in three

biophysically detailed and independently tuned multicompartmental pyramidal cell models ([14], [27]), two

of which are based on the Hu et al. 2009 model and involve the same morphology but with differing soma-

dendrite excitability balance (cell geometries are provided in the Supplementary Information: Figure S1

and Figure S2). This threshold is computed as a function of the spatial segregation of the Na_V subtypes

in the AIS by continuously varying their density profiles from fully overlapping to strongly separated

(Figure 1).

We show that Na_V separation enhances backpropagation with axonal stimulation but can impede it with

somatic stimulation. This asymmetrical result was not expected. To explain our results, we independently

modify the *right-shift* (V_{RS}) of selected $Na_V1.2$ gating variables and their respective time constants by an

amount ΔV_{RS} (i.e. $V_{RS} \longrightarrow V_{RS} + \Delta V_{RS}$). These modifications to $Na_V1.2$ gating are applied only in the

AIS.

Sweeping ΔV_{RS} (while clamping other gating variables to nominal V_{RS} values) reveals that (I) $Na_V1.2$

availability and its time constant explain how proximal $Na_V1.2$ promotes backpropagation with axonal

stimulation, and (II) the threshold of steady-state *activation* explains how $Na_V1.2$ suppresses backpropa-

gation and reduces excitability with somatic stimulation.

Being a feature of pyramidal cells, the plastic distribution of AIS Na_V subtypes that we model applies to

something like eight out of ten cortical neurons. We have demonstrated opposing effects on backpropagation

with orthodromic versus antidromic stimulation by altering said Na_V distribution. Various experimental

and computational techniques used to study the biophysical determinants of AIS excitability across the

lifespan have involved different stimulation sites. It is thus important to know whether and how the

spatial profile of Na$_V$ channel subtypes really enhances backpropagation in vivo, and whether moving the stimulating electrode can bias or even invert experimental findings, as our work demonstrates. Apart from explaining the dynamical mechanism behind the dependence of AP generation on AIS Na$_V$ distribution, we clearly show that the site of stimulation matters, a finding that is present robustly in different models and which merits experimental confirmation. Changes to AIS properties and the follow-on effects on backpropagation must affect the entire cortex.

2 Results

2.1 Hypothetical Na$_V$ distributions in the AIS

We begin with our implementation of the model from Hu et al. 2009 [14] (Hu-based model), using their morphology, K$_V$ and Na$_V$ kinetics. The standard AIS length in our model is 25 μm, based on measurements from [10]. A key feature of the Na$_V$ distribution that changes during development, is the extent to which the voltage-gated sodium channel subtypes Na$_V$1.2 and Na$_V$1.6 are localized in the proximal and distal AIS, respectively [19]. In these simulations, the relative proportion of Na$_V$1.2 versus Na$_V$1.6 at a given position along the AIS can be changed without affecting the total Na$_V$ density at any point (Equation 5).

Figure 1 shows how the parameters x and κ control the way Na$_V$ subtypes are spread out along the AIS. When x is at its highest value of 1, the subtypes Na$_V$1.2 and Na$_V$1.6 are spaced apart from each other, with Na$_V$1.2 concentrated in the proximal AIS and Na$_V$1.6 in the distal AIS, approximating the distribution observed in developing pyramidal neurons (see [19]). Decreasing x transforms this separated distribution into a uniform mix ($x \longrightarrow 0$) where Na$_V$1.2 and Na$_V$1.6 are distributed homogeneously. This can be seen in Figure 1a.

Every distribution except the uniform Na$_V$ mix has a location along the AIS at which the density of Na$_V$1.6 overtakes the Na$_V$1.2 density. That location, which we call the Na$_V$ crossover and denote κ, is also varied in our simulations (see Figure 1b; κ is a dimensionless length normalized by the AIS length.).

To cement our results, we will further apply identical transformations to the Na$_V$ distribution in a cell having a 'backward' AIS, that is, with *distal* Na$_V$1.2 and *proximal* Na$_V$1.6. The results from the backward AIS model are nearly a mirror image of our findings.

For each hypothetical Na$_V$ distribution, a short current pulse (1ms) is injected at a specific site, and

the minimum (i.e. threshold) pulse amplitude I (in nA) required to elicit a spike is determined. Brief pulse

durations separate the stimulation waveform from the intrinsic response of the cell. We define excitability

in terms of two thresholds: backpropagation threshold I_{BP} (AP leading to a spike in the distal dendrites)

and forward-propagation threshold I_{FP} (axonal AP threshold, recorded without regard to the amplitude

of the somatodendritic depolarization).

Current is injected either in the middle of the soma (somatic stimulation) or the axon just distal to the

AIS (axonal stimulation). Both are used by experimentalists [34], and certain pyramidal neurons are also

known to receive axo-axonic input at the AIS as well as somatodendritic input [6]. In both cases, forward

propagation refers to an AP travelling down the axon, and backpropagation always refers to an AP visible

as a spike in the dendrites. Backpropagation was deemed to have occurred if all apical dendritic tips

exceeded -63.0mV (i.e. a depolarization of 7.0mV above V_{rest}) following stimulation (see Supplementary

Information, Figure S3).

Figure 1: **Modifying the spatial distribution of Na$_V$ subtypes in the AIS while keeping the total conductance constant.** (**a**) The spatial separation of Na$_V$ subtypes in the AIS is varied using the parameter "x" with $\kappa = 0.5$. The top plot is a model setup with a separated distribution [14] of Na$_V$s in the AIS. The high threshold Na$_V$1.2 (indicated in blue) are concentrated close to the soma, and the low threshold Na$_V$1.6 (indicated in orange) are kept distal to the soma. Moving from top to bottom, both Na$_V$ subtypes are distributed ever more evenly along the AIS. We chose the parameter name "x" to vary the spatial separation of the AIS Na$_V$ distributions, because the separated distribution is x-shaped. Setting $x = 1$ in our simulations gives the separated distribution, and $x = 0$ gives the "flat" distribution wherein both Na$_V$ subtypes are uniformly mixed. (**b**) Variation of the crossover location (κ) of Na$_V$s in the AIS with $x = 0.5$. We have lengthened the AIS to 50µm in this graphic for visual clarity.

176   In the following sections, we implement the above Na$_V$ distributions in the Hu model [14]. Later, in

177   Section 2.6, we repeat this procedure in the model of Hay et al. [27]. The third model, an alternate tuning

178   of the Hu model with significant qualitative differences in its backpropagating action potential, is included

179 in the supplementary information (Section S1.4).

2.2 Somatic stimulation

181 In Figure 2, both negatively and positively sloped backpropagation threshold curves with respect to x are

182 present, indicating that Na_V separation can promote or impede backpropagation (respectively). Changes

183 in threshold can be as large as **30%**. Moving the Na_V crossover (κ) toward the distal AIS shifts the

184 backpropagation threshold curves upward. A qualitative change, namely the sign of the slope, occurs

185 around $\kappa = 0.4$.

Figure 2: **Somatic stimulation: combined effect of varying crossover location (κ) and Na_V separation (x) in the axon initial segment.** The threshold for forward AP propagation is the same as for backpropagation. Varying the separation parameter "x" from $x = 0$ to $x = 1$, the distribution of Na_V channels goes from flat (homogeneous) to separated, the latter approximating the distribution observed in developing pyramidal neurons (see Figure 1a). Note that curves for all values of κ converge to a single point at $x = 0$ since κ can have no effect when the two Na_V subtypes are uniformly distributed along the AIS. The lines have been drawn to guide the eye.

An intuitive explanation for this latter effect is that moving the crossover location away from the soma

causes the AIS to be dominated by $Na_V 1.2$ channels (see Figure 1b, $\kappa = 0.8$), which have a higher voltage

threshold than $Na_V 1.6$. APs still initiate in the distal AIS, but the dominant $Na_V 1.2$ renders the cell less

excitable. Further, for $\kappa \gtrsim 0.4$, the backpropagation threshold increases as we tend toward the separated,

x-shaped distribution of Na$_V$s. This behaviour is the opposite of what is observed for axonal stimulation

below and in [14]. We repeated these simulations with AIS length up to $100\mu m$ (Figure S11) and also

with stimulation at the main apical dendrite (Figure S13) instead of the soma, and obtained the same

qualitative results as Figure 2 (see Supplementary Information Section S1.4.1).

The negatively sloped curves do not necessarily imply that proximal Na$_V$1.2 promotes backpropagation

in the case of somatic stimulation. In those curves ($\kappa \lesssim 0.4$), the AIS is mainly populated with Na$_V$1.6

when $x > 0$. Also note that decreasing κ places more Na$_V$1.6 channels nearer to the soma (see Figure 1b,

$\kappa = 0.2$). In that case, the threshold-lowering effect of Na$_V$ separation could come from the increased total

Na$_V$1.6 density that results from increasing x when κ is relatively small, rather than from the proximal

accumulation of Na$_V$1.2 with increasing x. Further, increasing κ (which increases the ratio of Na$_V$1.2 to

Na$_V$1.6 in the AIS) raises the threshold for all curves in Figure 2 (see also Figure S12). It is then consistent

to postulate that for somatic stimulation, the backpropagation threshold is increased by AIS Na$_V$1.2 at all

values of x and κ, and Figure 2 is consistent with AIS Na$_V$1.6 enhancing excitability and backpropagation.

In other words, for **somatic stimulation**:

• when $\kappa < 0.5$ and $x > 0$, the AIS is dominated by Na$_V$1.6: increasing x increases the proportion of

total AIS Na$_V$ conductance due to Na$_V$1.6 (negative slope: separated distribution yields the lowest

backpropagation threshold).

• when $\kappa > 0.5$ and $x > 0$, the AIS is dominated by Na$_V$1.2: increasing x decreases the proportion of

total AIS Na$_V$ conductance due to Na$_V$1.6 (positive slope: separated distribution yields the highest

backpropagation threshold).

Lengthening the hillock with κ fixed also moves the crossover away from the soma. Curves with

negative slope in Figure 2 became positively sloped when the hillock was lengthened from $10\mu m$ to $30\mu m$

(Figure S14). The forward propagation threshold for somatic stimulation with a single $1ms$ current pulse

is not included in a separate figure since it is identical to the backpropagation threshold in this model.

This does not depend on the somatic injection site. The effect of Na$_V$ gating properties in the AIS on

backpropagation threshold is examined systematically in Section 2.5, Figure 6.

An informative variation on Figure 2 is shown in Figure 3c in which the AIS is "put on backward",

²¹⁷ such that $Na_V1.2$ is concentrated in the distal AIS and $Na_V1.6$ is proximal to the soma. As one might

²¹⁸ expect, the effect of varying x and κ in Figure 3 is opposite to what is seen in Figure 2, albeit with some

²¹⁹ new curvature at low κ. This reinforces the observation that proximal $Na_V1.6$ facilitates backpropagation

²²⁰ with somatic stimulation.

(a)

(b)

(c)

Figure 3: **Somatic stimulation with a flipped Na$_\mathrm{V}$ distribution: backward AIS.** When the AIS Na$_\mathrm{V}$ distribution is flipped proximal-to-distal, setting $x = 1$ concentrates Na$_\mathrm{V}$1.6 at the proximal AIS and Na$_\mathrm{V}$1.2 at the distal AIS —the opposite of what is observed in many pyramidal cells [14, 15, 16]. **(a)** AIS with proper longitudinal placement of Na$_\mathrm{V}$s. **(b)** AIS with a longitudinally flipped Na$_\mathrm{V}$ distribution. In both plots, $x = 0.5$ and $\kappa = 0.5$. **(c)** Somatic stimulation with AIS Na$_\mathrm{V}$s flipped as in **(b)**: This result is close to a mirror image of Figure 2. The lines have been drawn to guide the eye.

2.3   Axonal stimulation

With axonal stimulation (current injection just distal to the AIS), Na_V separation consistently lowers the backpropagation threshold (Figure 4). Contrary to somatic stimulation (Figure 2), moving the Na_V crossover (κ) toward the distal AIS shifts the backpropagation threshold curves downward.

Figure 4: **Axonal stimulation: effect of varying crossover location (κ) and Na_V separation (x) in the AIS on the backpropagation threshold** (see Figure 1). When computing the threshold, the stimulating current was limited to a maximum of $10nA$, to prevent unphysiological local depolarization at the stimulation site. Due to the smaller diameter of the axon (relative to the soma), $10nA$ is sufficient to depolarize the membrane potential to $\approx +80mV$ at the stimulation site, whereas the resting potential is $V_{rest} = -70mV$. To achieve backpropagation within that constraint (following axonal stimulation), our model required some amount of proximal $Na_V1.2$, delivered through the combined effects of Na_V separation ($x \gtrsim 0.5$) and a sufficiently distal crossover position $\kappa \gtrsim 0.4$. Separating the two Na_V subtypes ($x \to 1$) lowers the threshold, in agreement with the finding in [14] that proximal accumulation of $Na_V1.2$ promotes backpropagation, albeit due to different gating properties (Figure 6b). Increasing κ raises the proportion of $Na_V1.2$ (relative to $Na_V1.6$) in the AIS and lowers the backpropagation threshold as well. Threshold changes here are larger than for somatic stimulation (Figure 2). The lines have been drawn to guide the eye.

The decreasing threshold with respect to x in Figure 4 is consistent with the conclusion from [14], which used axonal stimulation, that proximal $Na_V1.2$ in the AIS promotes backpropagation. Our results for κ, with axonal stimulation, provide new support for their findings.

228 This agreement is interesting because our method of modifying the AIS Na$_V$ distribution (described

229 above in Figure 1) is quite different from their simulations. Our transformations deliberately preserve the

230 total Na$_V$ density at every AIS segment —if Na$_V$1.2 is removed, Na$_V$1.6 must take its place. Conversely, in

231 [14], the density profile of Na$_V$1.2 is scaled by a constant factor everywhere in the AIS, leaving the Na$_V$1.6

232 profile intact. We denote the scaling factor

$$\alpha_{\text{Na}_V 1.2} \geqslant 0. \tag{1}$$

That is, if the Na$_V$1.2 density profile is scaled down in [14], nothing is added to compensate for the missing

channels. Under the latter transformation, we expect that $\alpha_{\text{Na}_V 1.2} > 1$ would lower I_{BP} and $\alpha_{\text{Na}_V 1.2} < 1$

would raise I_{BP} in our models as well, since scaling the density profile of Na$_V$1.2 in a separated distribution

with a specified κ and $x > 0$ would scale the total AIS Na$_V$ conductance, especially at the proximal AIS.

We have reproduced this procedure in the Hay model, see Section 2.7.

It is one thing to say that reducing (increasing) the total density of voltage-gated sodium channels in

the proximal AIS, which happen to be Na$_V$1.2 channels, will raise (lower) the backpropagation threshold

(respectively). But since we preserved the local Na$_V$ density in our results (above), the changes to I_{BP} can

only be a manifestation of the spatial heterogeneity of sodium channel *gating properties*. In Section 2.5,

Figure 6, the *right-shift* (V_{RS}) of Na$_V$1.2 gating properties is modified in the AIS. Since *right-shift* is the

most important feature distinguishing Na$_V$1.2 from Na$_V$1.6 in this model, the analysis in Figure 6 explains

how the proximal accumulation of Na$_V$1.2 is able to simultaneously lower I_{BP} with axonal stimulation

(Figure 4) and raise I_{BP} with somatic stimulation (Figure 2) .

2.4 Forward propagation threshold

The forward-propagation threshold I_{FP}, also referred to as the AP threshold, is shown in Figure 5 for

the Hu-based model. With axonal stimulation only, it is possible to elicit an action potential without

creating sufficient depolarization in the apical dendrites to meet our strict criterion for backpropagation

(see Figure S4, Figure S3). Note, however, that the most distal dendrites depolarize to several mV above

their local resting potential (see Figure S4b). Stimulation amplitude is an order of magnitude lower than

in the case of I_{BP}. This is expected with axonal stimulation due to the high Na$_V$ density of the distal

AIS, its electrical isolation from the soma, its proximity to the stimulus, and our stringent definition of I_{BP} (Section S1.2). (Further, as discussed in [35], Hu et al.[14] built their model on [24], in which somatic invasion of the axonal action potential is reduced.)

As with I_{BP}, increasing x lowers I_{FP}. Na$_V$ separation concentrates Na$_V$1.6 in the distal AIS, making it more excitable in the portion nearer to the stimulation site. This finding is consistent with [14], who found that distal Na$_V$1.6 density places the lowest initiation threshold (and therefore the AP trigger zone) at the distal AIS. However, [33] has shown that cable properties are sufficient to explain why the trigger zone is located at the distal AIS (see Discussion). Moving the crossover distally ($\kappa \rightarrow 1$) increases the total proportion of Na$_V$1.2 in the AIS and thereby raises the I_{FP} threshold due to *activation right-shift*.

Figure 5: **Axonal stimulation: effect of x and κ on forward propagation threshold.** The trend for all constant κ curves is that raising the proportion of total AIS Na$_V$1.6 (by reducing κ) or concentrating Na$_V$1.6 in the distal AIS (by increasing x) lowers the threshold to initiate forward propagating action potentials (see Figure 1). Note that although this threshold current pulse is not sufficient to satisfy our strict backpropagation criterion (see Section S1.2), the most distal apical dendrites will be depolarized by several mV relative to their local resting potential (see Figure S4b). The lines have been drawn to guide the eye.

2.5   Modifying the *right-shift* of selected gating properties in the AIS

Our results from varying the Na$_V$ distribution may be counterintuitive. With axonal stimulation, concentrating low threshold Na$_V$1.6 channels at the distal AIS ought to promote forward propagation (and it does, see Figure 5), but why would concentrating the *high threshold* Na$_V$1.2 channels at the proximal AIS facilitate backpropagation? And how does the asymmetry come about, such that separating Na$_V$ subtypes can raise the backpropagation threshold with somatic stimulation, but always lowers it with axonal stimulation?

In this section, we perform a type of sensitivity analysis with respect to the effects of the *right-shift*ed Na$_V$1.2 subtype. Figure 6 allows us to isolate the effects of *activation right-shift* versus *availability right-shift* on the backpropagation threshold.

Na$_V$ subtypes are defined by their gating properties. Each Na$_V$ distribution (Figure 1) produces a corresponding spatial profile of gating properties, including *right-shift*. (Gating properties are detailed in Supplementary Information, see Figure S15.) In Figure 6, the AIS Na$_V$ distribution is fixed at $x = 1$. This spatial separation of Na$_V$s concentrates *right-shift* in the proximal AIS, by concentrating Na$_V$1.2 in that region (see Figure 1).

Our model sets the nominal *right-shift* of Na$_V$1.2 at $V_{RS} = 13.0$mV for compatibility with [14]. We use the parameter ΔV_{RS} to alter, in the AIS only, the *right-shift* of specific Na$_V$1.2 gating properties. (For additional details, see Section S1.6.2 and Section S1.6.3.) If a gating property (e.g. $m_\infty^{\mathrm{Na_V1.2}}$) is listed in the legend of Figure 6, then its voltage-dependence is displaced by ΔV_{RS} (see, e.g., Equation 2). Likewise, if a gating property is *not* displayed in the legend, its voltage-dependence will *not* be modified during the sensitivity analysis.

The *activation* $m^{\mathrm{Na_V1.2}}$ and *availability* $h^{\mathrm{Na_V1.2}}$ of real Na$_V$1.2 channels in nature are *right-shift*ed by similar amounts relative to their Na$_V$1.6 counterparts [20, 14, 12, 36]. (Although certain receptors can temporarily *right-shift activation* without shifting steady-state *availability* [37].) In our simulations, we can simultaneously decrease (or increase) the *right-shift* of $m^{\mathrm{Na_V1.2}}$ and $h^{\mathrm{Na_V1.2}}$ together, making the Na$_V$1.2 channels more (or less) similar to the Na$_V$1.6 channels in the AIS (respectively). This produces the 'reference curves' legended '🔵' in Figure 6a and Figure 6b. In those curves, ΔV_{RS} shifts the voltage-dependence of every Na$_V$1.2 gating property.

290   That is, as functions of membrane potential, the steady-states and time constants in the curves marked

291   '⬤' are $m_\infty^{\mathrm{Na_V}1.2} = m_\infty^{\mathrm{Na_V}1.2}(V - \Delta V_{\mathrm{RS}})$, $\tau_m^{\mathrm{Na_V}1.2} = \tau_m^{\mathrm{Na_V}1.2}(V - \Delta V_{\mathrm{RS}})$, $h_\infty^{\mathrm{Na_V}1.2} = h_\infty^{\mathrm{Na_V}1.2}(V - \Delta V_{\mathrm{RS}})$, $\tau_h^{\mathrm{Na_V}1.2} =$

292   $\tau_h^{\mathrm{Na_V}1.2}(V - \Delta V_{\mathrm{RS}})$ in the AIS.

(a) Somatic stimulation   (b) Axonal stimulation

Figure 6: **Sensitivity analysis of the backpropagation threshold to the *right-shift* of $\mathbf{Na_V}1.2$ gating properties.** Along each curve, the gating properties named in the legend have their *right-shift* changed from V_{RS} to $(V_{\mathrm{RS}} + \Delta V_{\mathrm{RS}})$, and the omitted gating properties are left unchanged (full definition and notation in Section S1.6.2). When $\Delta V_{\mathrm{RS}} = 0$, the *right-shift* is the reference value (or 'nominal value') of 13.0mV used for $\mathrm{Na_V}1.2$ in our simulations (see Section S1.6.2, V_{RS} indicated by small "●→" in Figure S15), around which we are performing this sensitivity analysis. The reference curve (legended ⬤) shows the net effect of *right-shift*ing all $\mathrm{Na_V}1.2$ properties on I_{BP}, via its slope. (It may be useful to imagine points on the reference curve as being pulled toward all the other curves that only change one property. The reference curve would then be the result of the combined pulls of those curves.) For each mode of stimulation, we identify the key gating properties through which *right-shift* controls backpropagation, by comparing the single property curves (▲$m_\infty^{\mathrm{Na_V}1.2}$, ✖$\tau_m^{\mathrm{Na_V}1.2}$, etc.) to the reference curve (⬤). **(a) Somatic stimulation:** The reference curve has a positive slope (*right-shift* raises I_{BP}), and it follows curves legended with $m_\infty^{\mathrm{Na_V}1.2}$ near the nominal point (i.e. near $\Delta V_{\mathrm{RS}} = 0$). Hence, I_{BP} is governed by $\mathrm{Na_V}$ steady-state *activation* and is insensitive to the *right-shift* of all $\mathrm{Na_V}$ time constants. **(b) Axonal stimulation:** The reference curve has a negative slope (*right-shift* lowers I_{BP}, i.e. promotes backpropagation), and it follows curves legended with $h_\infty^{\mathrm{Na_V}1.2}$ or $\tau_h^{\mathrm{Na_V}1.2}$. I_{BP} is then governed by proximal $\mathrm{Na_V}$ *availability*, owing to the *right-shift* of $\mathrm{Na_V}1.2$. Notably, with axonal stimulation, I_{BP} is also sensitive to the *right-shift* of $\tau_h^{\mathrm{Na_V}1.2}(V)$, the —voltage-sensitive— *availability* time constant. Results are summarized in **Table 1**. The lines have been drawn to guide the eye. In both plots, $x = 1.0$. On the left $\kappa = 0.7$(to increase the slope, see Figure 2), and on the right, $\kappa = 0.5$.

²⁹³ Figure 6 connects local gating properties in the AIS, and their influence on the backpropagation thresh-
²⁹⁴ old under somatic and axonal stimulation, to the effects of altering the Na$_\mathrm{V}$ distribution (seen above in
²⁹⁵ Figure 4 and Figure 2, respectively). For example, making ΔV_{RS} negative will *left-shift* the voltage-gated
²⁹⁶ sodium current in the proximal AIS, which is analogous to adding more proximal Na$_\mathrm{V}$1.6. However, this
²⁹⁷ is merely an analogy: With $x = 1$ and $\kappa \gtrsim 0.8$, the proximal AIS has only Na$_\mathrm{V}$1.2 channels, and positive
²⁹⁸ values of ΔV_{RS} will *right-shift* the sodium current in that area beyond what is attainable by changing the
²⁹⁹ local mix of Na$_\mathrm{V}$ subtypes.

³⁰⁰ The reference curve (●) in Figure 6a shows that *right-shift*ing Na$_\mathrm{V}$s in the AIS —akin to replacing
³⁰¹ Na$_\mathrm{V}$1.6 channels with more Na$_\mathrm{V}$1.2— *increases* I_{BP} for somatic stimulation. And the reference curve in
³⁰² Figure 6b confirms that proximal *right-shift* from Na$_\mathrm{V}$1.2 *lowers* I_{BP} for axonal stimulation.

³⁰³ Since ΔV_{RS} only affects Na$_\mathrm{V}$1.2 channels *within the AIS* (example provided in Figure S16b), we can de-
³⁰⁴ termine which *right-shift*ed gating properties drive the changes to I_{BP} that occur when the Na$_\mathrm{V}$ distribution
³⁰⁵ is altered. To make said observation, in Figure 6 we "shift-clamp" selected gating properties: We ignore
³⁰⁶ the experimental fact that Na$_\mathrm{V}$ *activation* and *availability* tend to *right-shift* in unison [20, 36, 38, 39], and
³⁰⁷ that gating variables' steady states and their voltage-sensitive time constants *right-shift* together as well
³⁰⁸ [40].

³⁰⁹ Instead, we isolate the effects of individual gating properties by

³¹⁰ 1. applying ΔV_{RS} to $h^{\mathrm{Na_V}1.2}$ independently of $m^{\mathrm{Na_V}1.2}$ (curves legended ✚ and ▼ respectively),

³¹¹ 2. applying ΔV_{RS} to $\tau_h^{\mathrm{Na_V}1.2}(V)$ independently of $h_\infty^{\mathrm{Na_V}1.2}(V)$, and likewise for $\tau_m^{\mathrm{Na_V}1.2}$, $m_\infty^{\mathrm{Na_V}1.2}$;
³¹²   (curves legended ■, ◆ and ✖, ▲ respectively),

³¹³ and compute the new backpropagation threshold $I_{BP}(\Delta V_{\mathrm{RS}})$. (For mathematical details, see Section 4.2.)

³¹⁴ An example of the latter is Equation 2 below, in which only $\tau_h^{\mathrm{Na_V}1.2}$ has its *right-shift* modified by ΔV_{RS}
³¹⁵ (see Figure S16b). The other three Na$_\mathrm{V}$1.2 variables have the nominal *right-shift* of 13mV. The $I_{BP}(\Delta V_{\mathrm{RS}})$

316 curves in Figure 6 that correspond to Equation 2 are legended $\blacksquare \tau_h^{\mathrm{Na_V}1.2}$:

$$\text{``}\blacksquare\tau_h^{\mathrm{Na_V}1.2}\text{''} \leftarrow \begin{cases} \tau_h^{\mathrm{Na_V}1.2} = \tau_h^{\mathrm{Na_V}1.2}(V - \Delta V_{\mathrm{RS}}) \\\\ h_\infty^{\mathrm{Na_V}1.2} = h_\infty^{\mathrm{Na_V}1.2}(V) \\\\ \tau_m^{\mathrm{Na_V}1.2} = \tau_m^{\mathrm{Na_V}1.2}(V) \\\\ m_\infty^{\mathrm{Na_V}1.2} = m_\infty^{\mathrm{Na_V}1.2}(V). \end{cases} \tag{2}$$

(Figure S16 visualizes the impact of Equation 2 on gating properties as a function of position at V_{rest}.)

To unpack these additional curves, we begin at the coordinate we will call 'the nominal point' in each

plot of Figure 6, which is the backpropagation threshold at $\Delta V_{\mathrm{RS}} = 0$, where all curves must intersect

by definition. Starting at the nominal point, as one moves leftward along a given curve ($\Delta V_{\mathrm{RS}} < 0$), the

gating properties indicated in the legend are *left-shift*ed (e.g. Equation 2), and the other gating properties

are left alone. Likewise, travelling away from the nominal point to the right ($\Delta V_{\mathrm{RS}} > 0$) will *right-shift* the

indicated properties, relative to their nominal kinetics (Figure S15).

Figure 6b reveals that, with axonal stimulation, the *right-shift*ed *availability* ($h^{\mathrm{Na_V}1.2}$) drives I_{BP}. Specif-

ically, the curves legended $\blacklozenge h_\infty^{\mathrm{Na_V}1.2}$, $\blacksquare \tau_h^{\mathrm{Na_V}1.2}$, and $\textcolor{purple}{\boldsymbol{+}} h_\infty^{\mathrm{Na_V}1.2}, \tau_h^{\mathrm{Na_V}1.2}$ show how $h_\infty^{\mathrm{Na_V}1.2}$ (the *availability* at

steady-state, as a function of membrane potential) and $\tau_h^{\mathrm{Na_V}1.2}$ (the voltage-dependent time constant of

availability) work together to promote backpropagation: They drive the reference curve ($\bullet$) downward

as ΔV_{RS} increases, in spite of the higher *activation* threshold. In other words: The threshold-lowering

effects that result from *right-shift*ing the *availability* overpower the opposing influence of *right-shift*ed *ac-

tivation* —on its own the latter would raise the threshold (see the curves: $\textcolor{cyan}{\blacktriangle} m_\infty^{\mathrm{Na_V}1.2}$ and $\textcolor{magenta}{\blacktriangledown} m_\infty^{\mathrm{Na_V}1.2}, \tau_m^{\mathrm{Na_V}1.2}$

in Figure 6b).

Further, removing the *right-shift* from $\tau_h^{\mathrm{Na_V}1.2}$ stops backpropagation: In the $\blacksquare \tau_h^{\mathrm{Na_V}1.2}$ curve of Fig-

ure 6b, all gating properties other than $\tau_h^{\mathrm{Na_V}1.2}$, including $h_\infty^{\mathrm{Na_V}1.2}$, retain their nominal *right-shift*, yet

backpropagation ceases (according to our strict BAP criterion, see Section S1.2) for axonal stimulation

when $\Delta V_{\mathrm{RS}} \lesssim -2\mathrm{mV}$.

For somatic stimulation, the *right-shift*ed *activation* ($m^{\mathrm{Na_V}1.2}$) drives I_{BP}. Travelling from right to

left in Figure 6a, the most significant decrease in threshold occurs in the curves legended $\textcolor{cyan}{\blacktriangle} m_\infty^{\mathrm{Na_V}1.2}$ and

🔻$m_\infty^{\mathrm{Na_V1.2}}, \tau_m^{\mathrm{Na_V1.2}}$ as the nominal *right-shift* is removed ($\Delta V_{\mathrm{RS}} \rightarrow -13.0\mathrm{mV} \implies V_{\mathrm{RS}} + \Delta V_{\mathrm{RS}} \rightarrow 0$, see

Figure S15). The 🔻$m_\infty^{\mathrm{Na_V1.2}}, \tau_m^{\mathrm{Na_V1.2}}$ curve differs negligibly from the 🔺$m_\infty^{\mathrm{Na_V1.2}}$ curve, showing that $m_\infty^{\mathrm{Na_V1.2}}$

right-shift dominates in raising the threshold near the nominal point, and the *right-shift* of $\tau_m^{\mathrm{Na_V1.2}}$ matters

little.

Our ΔV_{RS} results from Figure 6 are summarized in Table 1.

Table 1: **Summary of sensitivity analysis: Impact of *right-shift*ed Na$_{\mathbf{V}}$1.2 gating properties in the AIS on backpropagation threshold** (see Figure 6).

Type of Stimulation	reference curve 🔵	Increasing ΔV_{RS} of ***availability***		
		🟥$\tau_h^{\mathrm{Na_V1.2}}$	🔷$h_\infty^{\mathrm{Na_V1.2}}$	➕$h_\infty^{\mathrm{Na_V1.2}}, \tau_h^{\mathrm{Na_V1.2}}$
Axonal	$\downarrow$	$\downarrow$	$\downarrow$	$\downarrow$
Somatic	$\uparrow$	$\times$	$\downarrow$(slight)	$\downarrow$(slight)
		Increasing ΔV_{RS} of ***activation***		
		✖$\tau_m^{\mathrm{Na_V1.2}}$	🔺$m_\infty^{\mathrm{Na_V1.2}}$	🔻$m_\infty^{\mathrm{Na_V1.2}}, \tau_m^{\mathrm{Na_V1.2}}$
Axonal	$\downarrow$	$\uparrow$ (slight)	$\uparrow$	$\uparrow$
Somatic	$\uparrow$	$\times$	$\uparrow$	$\uparrow$

Arrows ($\downarrow$,$\uparrow$) indicate the sign of the **slopes** of backpropagation threshold curves in Figure 6a (somatic stimulation) and Figure 6b (axonal stimulation). A downward arrow ($\downarrow$) indicates that the backpropagation threshold I_{BP} decreases with increasing *right-shift*, applied to the gating properties specified above it. Likewise, an upward arrow ($\uparrow$) indicates that the threshold increases when the specified combination of Na$_V$1.2 variables is *right-shift*ed. In cells marked "$\times$" the effect of *right-shift* was negligible.

2.6 **Generalization to other models**

To demonstrate that our primary result —the separation of Na$_V$1.2 and Na$_V$1.6 into the proximal and

distal AIS, respectively, promotes backpropagation with axonal stimulation but can *impede or promote*

backpropagation with somatic stimulation— is not an artifact of our implementation of the model from

Hu et al. (2009) [14] used thus far, we have inserted Na$_V$ distributions analogous to Figure 1 into the model

of Hay et al. (2011) [27] below. (Also, in Section S1.4, we include an alternate tuning of the Hu model,

with a less excitable soma and robust backpropagation in the entire dendritic tree without attenuation.

Despite its significantly higher dendritic excitability and qualitatively different backpropagation pattern,

the results reported above are reproduced there as well.)

³⁵² We replaced the single population of Na$_V$s in the Hay model's **60μm** AIS with two Na$_V$ subtypes,

³⁵³ based on their original Na$_V$ kinetics: One population *left-shift*ed by **6mV** and the other *right-shift*ed by

³⁵⁴ **6mV**, relative to the original $V_{1/2}$, to represent Na$_V$1.6 and Na$_V$1.2 respectively. Our manipulations of

³⁵⁵ the Na$_V$ channels' distribution (varying κ and x) did not change the total Na$_V$ density in the AIS, which

³⁵⁶ was kept identical to their model (https://modeldb.science/139653). Further, we attached an additional

³⁵⁷ **400μm**-long section of passive cable to the end of the AIS, where their axon originally stopped, to allow

³⁵⁸ the AP to exit the AIS orthodromically as well as antidromically, as is the case in real neurons, in order

³⁵⁹ to make AP generation in the Hay model more realistic. This was necessary to recover our qualitative

³⁶⁰ results.

³⁶¹ Our intention was to modify the Hay model as little as was necessary, since its parameters are tailored

³⁶² to a specific neuron and morphology —they will not necessarily transfer well even between specimens of the

³⁶³ same cell type (see Hay et al., 2011 [27]). Presumably, the tuning may also be sensitive to the excitability

³⁶⁴ of newly attached compartments.

³⁶⁵ We note that Hay et al. optimized their models to fit experimentally observed somatic and dendritic

³⁶⁶ spiking patterns, including BAC firing, but their focus was not on action potential initiation. The models

³⁶⁷ that best fit their data had AP initiation in the soma rather than the AIS, but they provide an additional

³⁶⁸ model where APs were constrained to initiate in a **60μm** section named "axon", which had been set aside

³⁶⁹ due to excessive BAP attenuation (see [27]). Since we required a parameter tuning with AP initiation in

³⁷⁰ the AIS, the latter model was the necessary choice, despite its unrealistically strong attenuation of the

³⁷¹ backpropagated AP.

³⁷² In Figures 7 and 8 we register backpropagation in the Hay model [27] as either a spike in the soma, or

³⁷³ a depolarization of several **mV** in the apical dendrites, following current injection. The threshold was set

³⁷⁴ at **10mV** in these figures for the somatic criterion; and at **−70mV** when measuring the depolarization near

³⁷⁵ the bifurcation of the main apical dendrite, where $V_{\text{rest}} \cong -74.1$**mV**. See Figure S5.

³⁷⁶ Note the qualitative agreement between the Hay model implemented below and the Hu model above.

³⁷⁷ In Figure 7 (below), we simulate backpropagation following somatic stimulation. As above in Figure 2,

³⁷⁸ concentrating Na$_V$1.2 in the proximal AIS tends to raise the backpropagation threshold, and increasing

³⁷⁹ the proportion of total sodium conductance in the AIS allocated to Na$_V$1.6 lowers I_{BP}.

³⁸⁰ In Figure 8, we simulate backpropagation following axonal stimulation. As above in Figure 4 and

²²

Figure 5, the separated Na_V distribution ($x \rightarrow 1$) lowers the backpropagation threshold in the Hay model.

Quantitatively, Figure 8 is closer to Figure 5, suggesting that the concentration of low-threshold $Na_V1.6$ at the distal AIS, rather than the concentration of $Na_V1.2$ at the proximal AIS, promotes backpropagation. What is important to keep in mind is that, in both models, concentrating $Na_V1.2$ in the proximal AIS only lowered I_{BP} in the unphysiological case of depolarizing axonal current injection.

(a) Somatic criterion   (b) Apical criterion

Figure 7: **Somatic stimulation in the Hay model: Equivalency of apical vs. somatic backpropagation criteria.** Combined effect on the backpropagation threshold (I_{BP}, defined below) of varying crossover location (κ) and Na_V separation (x) in the axon initial segment. Note the qualitative and quantitative similarity to Figure 2. Varying the separation parameter "x" from $x = 0$ to $x = 1$, the distribution of Na_V channels goes from flat (homogeneous) to separated, the latter approximating the distribution observed in developing pyramidal neurons (see Figure 1a). Note that curves for all values of κ converge to a single point at $x = 0$ since κ can have no effect when the two Na_V subtypes are uniformly distributed along the AIS. Somatic backpropagation criterion $= 10.0$mV, apical backpropagation criterion $= -70.0$mV —see caption of Figure S5.

In Figure 7a and Figure 8a, backpropagation is registered if the somatic membrane potential exceeds 10.0mV. The threshold need not be this high, but it does not affect the results since the somatic depolarization is large. In Figure 7b and Figure 8b, backpropagation is recorded in the main apical dendrite just distal to its main bifurcation (where $V_{\text{rest}} \cong -74.1$mV) if the voltage exceeds -70mV. (See Figure S5a, Figure S5c.)

(a) Somatic criterion   (b) Apical criterion

Figure 8: **Axonal stimulation in the Hay model: Equivalency of apical vs. somatic backpropagation criteria.** In the Hay model, the backpropagation threshold (defined above) is identical to the AP threshold. There is nowhere for saltatory conduction to occur, as there is no excitable axon beyond the AIS. Varying the separation parameter "x" from $x = 0$ to $x = 1$, the distribution of Na_V channels goes from flat (homogeneous) to separated, the latter approximating the distribution observed in developing pyramidal neurons (see Figure 1a). Note that curves for all values of κ converge to a single point at $x = 0$ since κ can have no effect when the two Na_V subtypes are uniformly distributed along the AIS. Somatic backpropagation criterion $= 10.0$mV, apical backpropagation criterion $= -70.0$mV —see caption of Figure S5.

₃₉₁   Since the Na_V distribution changes throughout development, a further investigation —beyond the scope

₃₉₂ of this paper, as we will explain— would be to understand how accompanying developmental changes in

₃₉₃ morphological complexity and voltage-gated channel density elsewhere in the neuron [41] interact with

₃₉₄ developmental plasticity in the AIS. This would require new parameter sets at each iteration of the mor-

₃₉₅ phological complexity. Since Hay et al. [27] had to fit each morphology's parameter set to match firing

₃₉₆ patterns observed in real neurons, that procedure would need to be repeated. If sufficient experimen-

₃₉₇ tal data are not available to perform the fitting at each iteration, new electrophysiological experiments

₃₉₈ would be necessary at the corresponding developmental stages. That endeavour is beyond the scope of the

₃₉₉ present study. Also, there is experimental evidence that AIS plasticity is not limited to development [6].

₄₀₀ Our strategy was to restrict our investigation to the effects of varying the heterogeneous distribution of

₄₀₁ Na_V subtypes in the AIS on backpropagation threshold, with different modes of stimulation. Note, that

₄₀₂ the changing Na_V distributions we simulate are not strictly intended to replicate observed plasticity. Even

₄₀₃ if the Na_V distribution in the AIS of real neurons were static, modelling the hypothetical distributions

₄₀₄ would nonetheless assist in understanding its function; via the resulting changes to cellular excitability.

2.7   Rescaling the Na$_\text{V}$1.2 density profile by a uniform factor in the AIS

In this section, we rescale the Na$_\text{V}$1.2 density profile via the maximal conductance $\bar{g}_{\text{Na}_\text{V}1.2}$. At each segment of the AIS, $\bar{g}_{\text{Na}_\text{V}1.2}$ is multiplied by a positive number which we call the Na$_\text{V}$1.2 scaling factor, denoted $\alpha_{\text{Na}_\text{V}1.2}$. That is, at each point s in the AIS,

$$\bar{g}_{\text{Na}_\text{V}1.2}(s) \longrightarrow \alpha_{\text{Na}_\text{V}1.2}\bar{g}_{\text{Na}_\text{V}1.2}(s), \tag{3}$$

with $\alpha_{\text{Na}_\text{V}1.2} \geqslant 0$. In Figure 9, we observe that reducing the density of Na$_\text{V}$1.2, without adding any compensatory Na$_\text{V}$1.6 density, increases the threshold as expected. Even when Na$_\text{V}$1.2 is removed from the AIS and the proximal AIS contains no Na$_\text{V}$ channels, backpropagation is possible with somatic stimulation.

Figure 9: **Scaling the Na$_\text{V}$1.2 density profile in the AIS of the Hay model [27].** The backpropagation threshold is computed with somatic current injection (see Figure S5a, Figure S5b), while the Na$_\text{V}$1.2 density profile is scaled globally by $\alpha_{\text{Na}_\text{V}1.2}$. Here we have set $x = 1$ so that the Na$_\text{V}$1.2 and Na$_\text{V}$1.6 density profiles are separated (guaranteeing that the proximal AIS is exclusively populated with Na$_\text{V}$1.2), and $\kappa = 0.8$ so that the majority of the AIS (except the most distal region, see Figure 1b) contains Na$_\text{V}$1.2 and is therefore affected by $\alpha_{\text{Na}_\text{V}1.2}$.

In Figure 10 it is interesting to see, yet again, the sharp qualitative difference in the role of the Na$_\text{V}$1.2 subtype with axonal versus somatic stimulation. Figure 10a uses somatic stimulation, and backpropagation

remains possible when the $Na_V1.2$ channels are disabled entirely ($\alpha_{Na_V1.2} = 0$). With axonal stimulation however (Figure 10b), the effect of $\alpha_{Na_V1.2}$ was abrupt and binary, akin to a Heaviside function. I_{BP} was nearly flat, except the Hay neuron refused to produce a BAP when $\alpha_{Na_V1.2} \lesssim 0.32$ —some nonzero Na_V density was required in the proximal AIS for backpropagation.

(a) Somatic stimulation (b) Axonal stimulation

Figure 10: **Scaling the $Na_V1.2$ density profile in the AIS with somatic vs. axonal stimulation.** The backpropagation threshold is computed while the AIS $Na_V1.2$ distribution is scaled globally by $\alpha_{Na_V1.2}$. With somatic stimulation (a), backpropagation persists even when $Na_V1.2$ is removed ($\alpha_{Na_V1.2} = 0$). **However**, with axonal stimulation (b), backpropagation ends abruptly near $\alpha_{Na_V1.2} \lesssim 0.32$. Yet again, the importance of the proximal $Na_V1.2$ subtype and its qualitative effects on excitability depend heavily on the mode of stimulation. Density of data points increased in the vicinity of the vertical dashed line to detect backpropagation cutoff.

3 Discussion

In early development, pyramidal neurons concentrate $Na_V1.2$ in the proximal AIS, and $Na_V1.6$ in the distal AIS. As these cells mature, $Na_V1.6$ invades the proximal AIS, and the two Na_V subtypes lose their separated distribution [19]. We have investigated the effects of Na_V separation in the axon initial segment on the initiation and backpropagation of action potentials in three different pyramidal neuron models. In spite of their different parameters, axonal and dendritic morphology, and biophysics, all three models (Section 2.2, 2.3, 2.5, S1.4) indicated that the effects of the separated Na_V distribution depend on whether stimulation is orthodromic (e.g. somatodendritic input) or antidromic (e.g. axonal stimulation).

With somatic stimulation, the greater the proportion of $Na_V1.2$ in the AIS, relative to $Na_V1.6$, the

less excitable the cell becomes. This is contrary to past modelling which used axonal current injection [14], though it is consistent with the experimental results in [17] where somatic stimulation was used. The threshold-raising effect of proximal $Na_V1.2$ is confirmed by repeating the simulations with a model cell in which the AIS has been flipped longitudinally (Figure 3), placing $Na_V1.6$ proximally and $Na_V1.2$ distally in the AIS.

Our results for axonal stimulation agree qualitatively with and expand upon past modelling efforts [14]. In all three models, excitability is greatest when Na_V subtypes are separated in the AIS ('x-shaped distribution'). Further, in the Hu-based models (Figure 4, Figure S9), increasing the total proportion of $Na_V1.2$ in the AIS —by moving the Na_V crossover κ distally— promotes backpropagation as well. In the Hay-based model, removing Na_Vs from the proximal AIS halted backpropagation. We also find that increased distal $Na_V1.6$ concentration (which results from the separated distribution) lowers the AP threshold (Figure 5).

Testing both modes of stimulation can contribute to resolving inconsistencies between experiments such as [17] and [14], where stimulation was orthodromic in the former and antidromic in the latter. In [17], AP initiation was observed in pyramidal neurons which were engineered to be $Na_V1.6$-deficient. In those neurons, the AIS was populated entirely with $Na_V1.2$, however they still found that the AIS Na_V current was *left-shift*ed relative to the somatic current. From this and other observations, the authors in [17] suggest that the distribution of Na_V subtypes is not so important in shifting the local voltage-gated Na^+ current.

We note that, compared to control neurons, the $Na_V1.6$-deficient neurons' AIS Na_V current was *right-shift*ed, and the orthodromic AP threshold (amplitude of a 2ms current pulse [17]) was nearly doubled. This is consistent with our results and the modelling assumption that *right-shift* is associated with $Na_V1.2$ in the AIS —the model is agnostic about the molecular details. The decrease in excitability reported in [17] may have been even larger had they used more mature neurons. Their neurons were obtained from 4-5 week old mice, at which point the AIS will still be largely populated with $Na_V1.2$, whereas in wild type mice $Na_V1.6$ replaces much of the $Na_V1.2$ by 90 days [19, 28]. Our results indicate that with axonal stimulation, $Na_V1.6$-deficient cells may have a lower backpropagation threshold than the wild type.

The loss of the separated Na_V distribution in the AIS at later developmental stages, accompanied by the proximal localization of $Na_V1.6$, may enhance excitability to healthy orthodromic stimulation while

protecting against the backpropagation of ectopic activity from damaged axons into the soma and dendrites. Further, research into the genetic causes of autism spectrum disorder has revealed that $Na_V1.2$ knockout can enhance pyramidal cells' tendency to send action potentials and simultaneously reduce backpropagation (somatodendritic hypoexcitability) [18]. Whereas [18] reported an interplay between $Na_V1.2$ and K_V, in contrast, our results are explained by the spatial distribution of Na_V *right-shift* within the AIS (Table 1, Figure 6a). Indeed, the reduced excitability resulting from AIS $Na_V1.2$ owes to the asymmetric impact of *availability* on backpropagation in axonal versus somatic stimulation (Figure 6).

Although *right-shift*ing $Na_V1.2$ steady-state *availability* $h_\infty^{Na_V1.2}(V)$ in the AIS is necessary to promote backpropagation when stimulation is axonal, it is not sufficient on its own. Our modelling shows that the voltage-sensitive time constant $\tau_h^{Na_V1.2}(V)$ must be *right-shift*ed as well (Figure 6b, ■ $\tau_h^{Na_V1.2}$ curve).

It is clear why increasing ΔV_{RS} lowers I_{BP} in the ◆ $h_\infty^{Na_V1.2}$ curves of Figure 6b and Figure 6a: *Right-shift*ing steady-state $Na_V1.2$ *availability* increases Na^+ conductance at all voltages, because $h_\infty^{Na_V1.2}(V)$ is monotonically decreasing (Figure S15a). However, it was *not* obvious that removing the nominal *right-shift* from the voltage-sensitive time constant $\tau_h^{Na_V1.2}$ —without modifying steady-state *activation* ($m_\infty^{Na_V1.2}$) or *availability* ($h_\infty^{Na_V1.2}$)— should on its own be sufficient to eliminate the I_{BP}-lowering effects of $Na_V1.2$ for axonal stimulation. But that is what our model has demonstrated in the curve legended ■ $\tau_h^{Na_V1.2}$ of Figure 6b. It follows that the *x*-distribution's tendency to promote backpropagation is not merely a result of increased steady-state *availability* of proximal AIS Na_Vs, but is a dynamic effect —dependent on the *right-shift* of $\tau_h^{Na_V1.2}(V)$ as well.

There is an interplay between cable properties and the distribution of Na_Vs in determining the site of AP initiation [42]. Electrical isolation of the initiation site may amplify the effect of concentrating $Na_V1.6$ in the distal AIS. Via fluorescence imaging of intracellular Na^+ concentration following single action potentials, [33] located the greatest Na^+ influx at the middle of the AIS, whereas the distal AIS (initiation site) had only $1/4$ of this maximum. They inferred that the density of Na_V channels decreases toward the initiation site, and thus Na_V density does not determine the precise location where APs begin. Although [33] did not require $Na_V1.6$ accumulation at the distal AIS to explain the distal location of the initiation site, the authors suggest that local Na_V density can have a large effect on neuronal excitability. Temperature may also play a role in local AIS Na^+ influx measurements due to the spatial separation of Na_V subtypes. For high-speed spatiotemporal imaging of sodium influx, the pyramidal neurons in [33] and

[17] were cooled to 21℃. $Na_V1.2$ and $Na_V1.6$ differ in their responses to temperature changes [16]; thus, a deeper exploration of the effects of temperature on AP initiation is warranted. The temporal resolution of Na^+ influx measurements continues to improve: [43] achieved a resolution of 0.1ms imaging pyramidal cells in mouse brain slices. Another order of magnitude improvement may be sufficient to discern the local contributions of Na_V subtypes to AP initiation. The qualitative dependence of the backpropagation threshold on the somatic-versus-axonal mode of stimulation is compatible with distal AP generation as found in [33, 14] and in our work, but does not seem to rely crucially on the precise determinants of AP onset position; it relies rather on the *activation* and *availability* properties, and the kinetics of the latter.

Our model neurons were kept identical in all results presented above; only the AIS was altered. Our results therefore can only be explained by the distribution of Na_V subtypes (or, the distribution of *right-shift*ed Na_V gating properties) within the AIS. Given the τ_h-dependence of the antidromic backpropagation threshold in Section 2.5 and the differential temperature sensitivity of $Na_V1.2$ versus $Na_V1.6$ [16], there is good reason to expect that the effects of Na_V separation predicted here will be temperature-dependent.

In summary, we have simulated a range of hypothetical Na_V distributions in the axon initial segment of three 3D-reconstructed biophysical pyramidal cell models, including two distinct morphologies and three different parameter tunings. Our modelling shows that the spatial profile of $Na_V1.2$ and $Na_V1.6$ in the AIS and the kinetics of their *availability* and *activation* are important determinants of excitability and the backpropagation threshold. We predict that the separation of Na_V subtypes observed in early development has an asymmetrical effect on excitability which depends on whether the neuron is stimulated orthodromically or antidromically. With orthodromic stimulation, Na_V separation impedes backpropagation and reduces excitability unless the crossover is brought close to the soma. Backpropagation and excitability are both enhanced by Na_V separation when stimulation is antidromic. Maintaining a static Na_V distribution, we altered the *right-shift* of selected $Na_V1.2$ gating properties. This revealed that steady-state *activation right-shift* controls the orthodromic backpropagation threshold, and dynamic *availability right-shift* is necessary to explain the antidromic threshold. Furthermore, given that learning is linked to backpropagation, the evolving separation of the Na_V subtypes may impact synaptic weight modification across developmental stages.

4   Methods

The pyramidal cell models were implemented in NEURON 8.0 [44] via Python. For cell geometry, local membrane properties, additional simulations, and a variety of calculations, clarifications, and definitions, see Supplementary Information (Section 8), which has its own table of contents.

Our implementation of the Hay model (https://modeldb.science/230326) is detailed in Section 2.6. Aside from modifying the *right-shift* in axonal Na_V channels to create $Na_V1.2$ and $Na_V1.6$ variants in the AIS, and attaching an additional passive section to the end of the axon, our Hay-based model is biophysically and morphologically identical to the original. Section 2.7 is an exception to this, since the total Na_V conductance in the AIS was modified via $\alpha_{Na_V1.2}$.

Our Hu-based models [14] use the reconstructed morphology of a Layer 5 pyramidal neuron from cat visual cortex, modified from [24] (see SI, Section S1.1). Every compartment has explicit intracellular and extracellular concentrations of sodium, potassium, and chloride ions. The Nernst potentials E_{Na^+}, E_{K^+}, E_{Cl^-} are calculated locally from each compartment's specific ionic concentrations, which respond to transmembrane currents. Transmembrane concentration gradients of Na^+ and K^+ are maintained via active transport (Na^+/K^+-pump), and all ions are subject to longitudinal diffusion, both intra- and extracellular, implemented using NEURON's RxD facility [45]. The cell maintains a resting potential $V_{rest} \cong -70mV$ at steady-state, and restores this state following stimulation. The biophysics that governs local ion concentrations (and Nernst potentials) in the Hu-based model is summarized in Section 4.3.

4.1   AIS - Na_V density profiles

In our model, the density profiles of $Na_V1.2$ and $Na_V1.6$ are left- and right-handed sigmoidal functions (respectively) of normalized length s along the AIS. The proximal end of the AIS is located at $s = 0$, and the distal end is located at $s = 1$. The channel densities are expressed as maximal conductances $\bar{g}_{Na_V1.2}$ (s) and $\bar{g}_{Na_V1.6}$ (s), where the total maximal Na_V conductance $\bar{g}_{Na_V}$ is constant along the AIS:

$$\bar{g}_{Na_V} = \bar{g}_{Na_V1.2}(s) + \bar{g}_{Na_V1.6}(s) = const. \tag{4}$$

535   The density profiles are given by

$$
\begin{cases}
\bar{g}_{\mathrm{Na_V}1.2}(s) & = \dfrac{\bar{g}_{\mathrm{Na_V}}}{2}\Big(1 - x \cdot \tanh\big(\sigma(s-\kappa)\big)\Big), \\[2em]
\bar{g}_{\mathrm{Na_V}1.6}(s) & = \bar{g}_{\mathrm{Na_V}} - \bar{g}_{\mathrm{Na_V}1.2}(s) \\[1em]
& = \dfrac{\bar{g}_{\mathrm{Na_V}}}{2}\Big(1 + x \cdot \tanh\big(\sigma(s-\kappa)\big)\Big).
\end{cases}
\tag{5}
$$

We chose the hyperbolic tangent function $\tanh(s)$, but other sigmoidal functions would do just as well. The

parameter x controls the separation of the $\mathrm{Na_V}$ distribution, that is, how separated the two $\mathrm{Na_V}$ subtypes

are. When $x = 0$, the distribution becomes flat —$\mathrm{Na_V}1.2$ and $\mathrm{Na_V}1.6$ are mixed uniformly along the AIS.

When $x = 1$, the proximal end of the AIS contains only $\mathrm{Na_V}1.2$, and the distal end of the AIS contains

only $\mathrm{Na_V}1.6$. The parameter σ is the reciprocal of the 'transition width' of the AIS $\mathrm{Na_V}$ distributions

normalized by the AIS length. In all simulations shown here, $\sigma = 10.0$. Additional details are provided in

Section S1.5.

4.2   Shift-Clamping and the Hodgkin-Huxley model

544   In the Hodgkin-Huxley model [40] a gating variable u evolves according to its voltage-dependent forward

545   and backward transition rates $\alpha_u(V)$ and $\beta_u(V)$ as

$$
\frac{du}{dt} = \alpha_u(V)\big[1 - u\big] - \beta_u(V)u,
\tag{6}
$$

546   where u could be $\mathrm{Na_V}$ *activation* m or *availability* h, or $\mathrm{K_V}$ *activation* n, etc. This can be rewritten using

547   the steady-state $u_\infty(V)$ and voltage-dependent time constant $\tau_u(V)$ of the gating variable

$$
\frac{du}{dt} = \frac{u_\infty(V) - u}{\tau_u(V)};
\tag{7}
$$

548   where u_∞ and τ_u are computed from α_u and β_u via

$$
u_\infty(V) = \frac{\alpha_u(V)}{\alpha_u(V) + \beta_u(V)} \quad \text{and} \quad \tau_u(V) = \frac{1}{\alpha_u(V) + \beta_u(V)} \quad .
\tag{8}
$$

549   When shifting the voltage-dependence of u_∞ by ΔV_{RS}, it is natural to assume that one should apply

the same shift to τ_u given Equation 8, since u_∞ and τ_u are both functions of $\alpha_u(V)$ and $\beta_u(V)$ in such models. However, our simulations can shift $u_\infty(V)$ or $\tau_u(V)$ independently of one another: e.g. $\tau_u'(V) = \tau_u(V - \Delta V_{RS})$, $u_\infty'(V) = u_\infty(V)$. The forward and backward rates become

$$\alpha_u' = \frac{u_\infty'(V)}{\tau_u'(V)} \quad \text{and} \quad \beta_u' = \frac{1 - u_\infty'(V)}{\tau_u'(V)}. \tag{9}$$

Putting this to use, one can modify the *right-shift* of combinations of

$$\left\{ \tau_h^{\mathrm{Na_V}1.2}(V), \ h_\infty^{\mathrm{Na_V}1.2}(V), \ \tau_m^{\mathrm{Na_V}1.2}(V), \ m_\infty^{\mathrm{Na_V}1.2}(V) \right\}, \tag{10}$$

by adding "$-\Delta V_{RS}$" to the argument of the selected variables' $u_\infty(V)$s or $\tau_u(V)$s.

4.3   Biophysics, Hu-based models

Action potentials propagate via the cable equation

$$C \frac{\partial V}{\partial t} = \frac{d}{4R_a} \frac{\partial^2 V}{\partial s^2} - I_{membrane}, \tag{11}$$

where V is the membrane potential, C is the specific membrane capacitance, d is the neurite diameter, R_a is the axial resistance, s is the position along the axis of the cable, and $I_{membrane}$ is the total transmembrane current density of all ion species in the model.

   In the Hu-based model, each compartment has explicit intracellular and extracellular concentrations of sodium, potassium, and chloride ions. We denote the intracellular/extracellular concentration of a given ionic species "Z" as $[Z]_{in}$, $[Z]_{out}$ respectively. These concentrations depend on the spatial coordinate —i.e. $[Z]_{in} = [Z]_{in}(s)$— but that is not written explicitly, to simplify the notation. The Nernst potentials (reversal potentials) E_{Na^+}, E_{K^+}, E_{Cl^-} of Na^+, K^+, and Cl^- are not fixed parameters but are instead determined by the intracellular and extracellular concentrations of those ions:

$$E_Z(s) = -\frac{k_B T}{q_Z} \ln\left(\frac{[Z]_{in}}{[Z]_{out}} \right). \tag{12}$$

   Transmembrane concentration gradients of Na^+ and K^+ are governed by active transport (Na^+/K^+-

pump) and longitudinal diffusion. At each time step, ionic concentrations all over the cell are updated

using transmembrane currents (Equation 15) and Fick's law. At the jth compartment this gives:

$$
\begin{cases}
\dfrac{\partial}{\partial t}[Z]^{j}_{\text{in}} = -\left(\dfrac{A^{j}}{F\,Vol^{j}_{\text{in}}}\right)I^{j}_{Z} + D_{Z}\nabla^{2}[Z]^{j}_{\text{in}} \\[4mm]
\dfrac{\partial}{\partial t}[Z]^{j}_{\text{out}} = \left(\dfrac{A^{j}}{F\,Vol^{j}_{\text{out}}}\right)I^{j}_{Z} + D_{Z}\nabla^{2}[Z]^{j}_{\text{out}},
\end{cases}
\tag{13}
$$

where I^{j}_{Z} is the transmembrane current density of ion species Z at compartment j, with Z = Cl⁻, K⁺,

Na⁺. D_{Z} denotes the diffusion coefficient of ion Z. A^{j} and $Vol^{j}_{\text{in(out)}}$ are (respectively) the membrane

area and intracellular/extracellular volume at the jth compartment. F is the Faraday constant. The total

transmembrane current density at the jth compartment is

$$
I^{j}_{membrane} = I^{j}_{\text{Cl}^{-}} + I^{j}_{\text{K}^{+}} + I^{j}_{\text{Na}^{+}}.
\tag{14}
$$

Omitting the compartment index j, the specific transmembrane currents are

$$
I_{membrane} :
\begin{cases}
I_{\text{Cl}^{-}} = g_{\text{Cl}^{-}}(V - E_{\text{Cl}^{-}}) \\[2mm]
I_{\text{K}^{+}} = (g_{\text{K}_{\text{V}}} + g_{\text{K, leak}})(V - E_{\text{K}^{+}}) - 2I_{pump} \\[2mm]
I_{\text{Na}^{+}} = (g_{\text{Na}_{\text{V}}} + g_{\text{Na, leak}})(V - E_{\text{Na}^{+}}) + 3I_{pump}.
\end{cases}
\tag{15}
$$

$g_{\text{Cl}^{-}}$, $g_{\text{K, leak}}$, and $g_{\text{Na, leak}}$ are passive leak conductances whereas $g_{\text{K}_{\text{V}}}$ and $g_{\text{Na}_{\text{V}}}$ have voltage-gated

Hodgkin-Huxley (HH)-style kinetics (Equation S6). Since channels are nonuniformly distributed along

the cell membrane, conductances vary with location. I_{pump} is the net current produced by the Na⁺/K⁺-

pump as a function of $[\text{K}^{+}]_{\text{out}}$ and $[\text{Na}^{+}]_{\text{in}}$,

$$
I_{pump} = I_{maxpump}\left(1 + \dfrac{K_{M_{\text{K}^{+}}}}{[\text{K}^{+}]_{\text{out}}}\right)^{-2}\left(1 + \dfrac{K_{M_{\text{Na}^{+}}}}{[\text{Na}^{+}]_{\text{in}}}\right)^{-3},
\tag{16}
$$

where $I_{maxpump}$ controls the maximal pump current, $K_{M_{\text{K}^{+}}}$ and $K_{M_{\text{Na}^{+}}}$ are Michaelis-Menten kinetic con-

stants, and the Na⁺ and K⁺ currents flowing through the pump are $I_{\text{Na}^{+},pump} = 3I_{pump}$ and $I_{\text{K}^{+},pump} =$

$-2I_{pump}$. (Calcium dynamics are omitted in this section since Hu et al. [14] did not include the dendritic calcium spike initiation zone —see [35]. In Section 2.6 we include the Hay model, which features state-of-the-art calcium dynamics.)

4.4   Data availability

The simulation software that produces the results in this paper and the plotted data will be made available on ModelDB at https://modeldb.science/267088. Also, the Supplementary Information includes tables of parameters that detail the model setup.

4.5   Code availability

Model code will be posted on ModelDB upon publication at https://modeldb.science/267088.

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6   Author contributions

B. Barlow: conceptualization, model development, implementing the models and curating the outputs, coding, optimizing, model validation, figure preparation, and manuscript writing and revising; A. Longtin: conceptualization, model development, model validation, manuscript editing; and B. Joós: conceptualization, model development, model validation, manuscript editing. B. Joós and A. Longtin jointly supervised this work.

7 Competing interests

The authors declare no competing interests.

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8   Supplementary information

Contents

S1.1   Model: pyramidal cell geometry

Figure S1 displays the first of the two neurons used in this paper. The dendritic morphology is a digital reconstruction of a Layer 5 pyramidal neuron from cat visual cortex, modified from [24]. These neurons have dendrites roughly as tall as the thickness of the cortex (several mm) and axon initial segment length similar to the width of a human hair (tens of µm [9]).

Figure S1: **Geometry from the Hu model [14]: Layer 5 pyramidal neuron from cat visual cortex, modified from [24].** Somatodendritic morphology is digitally reconstructed from a real cell; hillock, AIS, and axon are added. Image created using blenderNEURON: blenderNEURON.org, blender.org.

The same reconstructed cell geometry was used in [14]. A cylindrical axon similar to that used in [14] was attached to the reconstructed soma by a 10µm long tapered hillock. The axon proper includes fifteen nodes of Ranvier (gray dots on the axon in Figure S3) separated by myelinated 100µm internodes. The axon initial segment length was set to $\ell = 25.0$µm, consistent with [10]. Voltage-gated channels are present all over the cell. Channel densities and passive leaks are given as conductances. The local conductances vary with position —representative values have been tabulated in Section S1.8.

In past modelling, there is sometimes a long section of bare axon following the AIS, or myelination may begin immediately at the end of the AIS. To ensure our results did not depend on this morphological feature, we ran simulations (axonal and somatic stimulation) with and without a 400µm section of bare axon separating the AIS from the first internode. The effects of Na$_\text{V}$ distribution, summarized in Figures S7 and S9, were qualitatively similar and similar in magnitude with and without the bare axon.

Figure S2: **Morphology from Hay et al. [27].** In the Hay model (https://modeldb.science/230326), the AIS consists of two straight NEURON Sections called "axon[0]" and "axon[1]", each 30μm in length, making the AIS 60μm long. The diagonal segment leading directly to the soma on the right is a 400μm long passive cable attached to the end of the AIS.

S1.2 Spikes and backpropagation in the Hu-based model

When pyramidal cells spike, the action potential can travel backward into the dendrites. This phenomenon is called backpropagation. For example, Figure S3 shows the response of the neuron following a somatic current pulse just above (left) and just below (right) the backpropagation threshold I_{BP}. Peak voltage is recorded across the entire cell model. The peak voltage at the tips of the dendrites is indicated in orange stars ★ and has a higher amplitude, consistent with the sealed-end effect. Backpropagation was deemed to have occurred if all apical dendritic tips exceeded -63.0mV (i.e. a depolarization of **7.0mV** above V_{rest}) following stimulation.

(a) Somatic stimulation, $I \gtrsim I_{BP} = I_{FP}$ (b) Somatic stimulation, $I < I_{BP} = I_{FP}$

Figure S3: **Backpropagation with somatic stimulation.** Each data point maps to a location in the reconstructed pyramidal neuron. On the abscissa, negative values indicate that a datapoint is located in the soma or dendrites, and positive values correspond to the hillock, AIS, and axon. (The correspondence between the abscissa and cell morphology is illustrated in Figure S6.) ($x = 1, \kappa = 0.7$) This and similar figures are inspired by "Figure 4" of [11].

Note the qualitative change that occurs in the peak dendritic voltages of Figure S3a and Figure S4a, when the cell is above threshold. A minuscule increase in the injected current amplitude has caused the entire main apical dendrite to depolarize well above -40mV, despite being mostly below -60mV when the current was slightly below this threshold. Note the attenuation in the peak voltage when comparing the basal dendrites to the apical tips. Also note the variety of different peak voltages in the dendrites, compared to the subthreshold condition. Our backpropagation criteria for the Hu models required this qualitative change since it was a robust feature of those models. Recall also that the purpose of the

dendrites in our model is to define a backpropagation threshold, not necessarily to mimic the detailed features of backpropagation. For our purposes, it is enough that the dendrites exhibit a threshold, and that threshold changes as a result of altering the distributions of Na_Vs in the AIS.

(a) Axonal stimulation, $I \gtrsim I_{BP} > I_{FP}$

(b) Axonal stimulation, $I_{BP} > I > I_{FP}$

Figure S4: **Axonal stimulation in the Hu-based model: spikes with and without backpropagation —by our stringent criterion.** Current is injected just distal to the AIS. Each data point maps to a location in the reconstructed pyramidal neuron. (The correspondence between the abscissa and cell morphology is illustrated in Figure S6.) In **(a)**, an action potential (AP) has backpropagated. Note the variability of V_{peak} in the somatodendritic region of the neuron, and the significant attenuation as the wave travels into the distal dendrites. In **(b)**, an AP has occurred but the pattern of depolarization in the dendrites does not satisfy the backpropagation criterion we have used for this model. Note that the peak voltage in the soma and dendrites remains nearer to the resting potential $\approx -70\text{mV}$, never exceeding -40mV. Also note the lack of variability in the somatodendritic V_{peak}. The qualitative change in these two plots occurs sharply, just above $I_{BP} \approx 2.7\text{nA}$ ($x = 1, \kappa = 0.4$). By some definitions, both of these scenarios would be considered backpropagation, since there is always a few mV of depolarization in the most distal dendrites. As this qualitative change is a robust feature of the Hu-based model, we have defined backpropagation in those simulations to require it. In defining a forward propagation threshold (I_{FP}), we call the scenario on the right, where an AP has been sent down the axon orthodromically from the stimulation site (i.e. to the right in this panel) "forward propagation" or "forwardprop" regardless of the amplitude of the somatodendritic depolarization. This and similar figures are inspired by "Figure 4" of [11].

S1.3   Spikes and backpropagation in the Hay-based model

The backpropagation criteria we used with the Hay model[27] are given in the caption of Figure S5.

(a) Somatic stimulation, $I \gtrsim I_{BP}$

(b) Somatic stimulation, $I \lesssim I_{BP}$

(c) Axonal stimulation, $I \gtrsim I_{BP}$

(d) Axonal stimulation, $I \lesssim I_{BP}$

Figure S5: **Backpropagation criteria in the Hay-based model.** Each data point maps to a location in the reconstructed pyramidal neuron. On the abscissa, negative values indicate that a data point is located in the soma or dendrites, and positive values correspond to the AIS and passive cable. (The correspondence between the abscissa and cell morphology is illustrated in Figure S6.) In (**a**) and (**c**) backpropagation has occurred, whereas in (**b**) and (**d**), the stimulation is (just) below the BAP threshold. In the model, backpropagation was recorded either at the soma (neighbouring the left end of the section labelled "AIS_0", membrane potential exceeding $10\mathrm{mV}$), or in the apical dendrites (just distal to the main bifurcation of the main apical dendrite, membrane potential exceeding $-70\mathrm{mV}$). The resting potential was $\cong -80.5\mathrm{mV}$ at the soma, and $\cong -74.1\mathrm{mV}$ at the apical recording site (see legend).

In Figure S5, compare the depolarization of the distal AIS ('AIS_1' in the legend) in the Hay model [27] when current is injected somatically versus axonally, with the neuron just below I_{BP}: In the somatic case (Figure S5b) the distal AIS never reaches $-60\mathrm{mV}$, while in the axonal case (Figure S5d) it exceeds

−50mV. Hay et al. did not include an axon[27], and here the AIS is followed by a passive cable, rather than an excitable axon composed of myelinated internodes segmented by nodes of Ranvier. Hence a forward-propagation threshold I_{FP} is ill-defined in this model. Were the Hay model to include such an axon, the increased depolarization of the distal AIS in (Figure S5d) compared to (Figure S5b) would be sufficient to cause an axonal AP in the former without doing so in the latter. Thus we argue, that the ability of the Hu-based model —with its excitable axon— to generate APs without meeting our criterion for backpropagation (Figure S4b), is an artifact of axonal stimulation.

S1.4   Alternate tuning of Hu-based model

In this tuning, backpropagation is robust. A high amplitude, regenerative BAP infiltrates the entire dendritic tree. We redefined the threshold criterion such that backpropagation was deemed to have occurred if all apical dendritic tips exceeded −10.0mV following stimulation. The higher threshold value was appropriate to record backpropagation due to the robust BAP, which did not show attenuation (see Figure S6). Although this tuning diverges from the qualitative features of BAPs in real pyramidal cells, at least for single action potentials [26, 27], the relationship between the backpropagation threshold and the Na_V distribution presented in Section 2 was preserved again (see the figures below).

That is, despite the significant qualitative differences between the tuning of the Hu et al. [14] based model below (Figure S6) which lacks BAP attenuation, the other Hu et al. based model above in the main text (Section 2.2, Section 2.3) which we modified for BAP attenuation, and the Hay et al. [27] based model above in Section 2.6, qualitative effects of modifying the Na_V distribution in the AIS are identical, and for somatic stimulation they are quantitatively similar as well. This can be clearly concluded by comparing Figure S7, Figure 2, and Figure 7.

Figure S6: Spikes with and without backpropagation: Each data point maps to a location in the reconstructed pyramidal neuron (compare with the cell morphology above the plot). On the abscissa, negative values indicate that a datapoint is located in the soma or dendrites, and positive values correspond to the hillock, AIS, and axon. Beginning on the right-hand side: an action potential (AP) has occurred following axonal stimulation (current injected just distal to the AIS). Note that the peak voltage in the soma and dendrites remains near the resting potential ≈ -70mV, indicating that backpropagation did not occur. We call this scenario where an AP has been sent down the axon orthodromically from the stimulation site (i.e. to the right in this panel) "forward propagation" or "forwardprop" regardless of the amplitude of the somatodendritic depolarization. To the left is an AP that backpropagated: the entire cell spiked, in this case following somatic stimulation; backpropagation can also occur following axonal stimulation. The somatodendritic peak voltages are indicated by a blue box in each case. This and similar figures are inspired by "Figure 4" of [11].

Figure S7: Somatic Stimulation: Combined effect of varying crossover location (κ) and Na$_\text{V}$ separation (x) in the axon initial segment. The threshold for forward AP propagation is the same as for backpropagation. Varying the separation parameter "x" from $x = 0$ to $x = 1$, the distribution of Na$_\text{V}$ channels goes from flat (homogeneous) to separated, the latter approximating the distribution observed in developing pyramidal neurons (see Figure 1a). Note that curves for all values of κ converge to a single point at $x = 0$ since κ can have no effect when the two Na$_\text{V}$ subtypes are uniformly distributed along the AIS. The lines have been drawn to guide the eye.

(a)

(b)

(c)

Figure S8: When the AIS Na_V distribution is flipped, setting $x = 1$ concentrates $Na_V1.6$ at the proximal AIS and $Na_V1.2$ at the distal AIS —the opposite of what is observed in many pyramidal cells [14, 15, 16]. (a) AIS with proper longitudinal placement of Na_Vs. (b) AIS with a longitudinally flipped Na_V distribution. In both plots, $x = 0.5$ and $\kappa = 0.5$. (c) Somatic stimulation with AIS Na_Vs flipped as in (b): This result is close to a mirror image of Figure S7. The lines have been drawn to guide the eye.

Figure S9: Axonal Stimulation: Effect of varying crossover location (κ) and Na_V separation (x) in the AIS on the backpropagation threshold (see Figure 1). When computing the threshold, the stimulating current was limited to a maximum of **10nA**, to prevent unphysiological local depolarization at the stimulation site. Due to the smaller diameter of the axon (relative to the soma), **10nA** is sufficient to depolarize the membrane potential to $\approx$ **+80mV** at the stimulation site, whereas the resting potential is $V_{\text{rest}} = -70\text{mV}$. To achieve backpropagation within that constraint (following axonal stimulation), our model required some amount of proximal $Na_V1.2$, delivered through the combined effects of Na_V separation ($x \gtrsim 0.5$) and a sufficiently distal crossover position $\kappa \gtrsim 0.4$. Separating the two Na_V subtypes ($x \to 1$) lowers the threshold, in agreement with the finding in [14] that proximal accumulation of $Na_V1.2$ promotes backpropagation, albeit due to different gating properties (Figure 6b). Increasing κ raises the proportion of $Na_V1.2$ (relative to $Na_V1.6$) in the AIS and lowers the backpropagation threshold as well. Threshold changes here are larger than for somatic stimulation (Figure S7). The lines have been drawn to guide the eye.

Figure S10: Axonal Stimulation: Effect of x and κ on forward propagation threshold. The trend for all constant κ curves is that raising the proportion of total AIS $Na_V1.6$ (by reducing κ) or concentrating $Na_V1.6$ in the distal AIS (by increasing x) lowers the threshold to initiate forward propagating action potentials (see Figure 1). Note that this threshold current pulse is not sufficient to achieve backpropagation. The effect of Na_V separation is much smaller here than for the backpropagation threshold. The lines have been drawn to guide the eye.

S1.4.1   Additional simulations

In the main text, we found that with a **25μm** AIS, the slope of I_{BP} versus x for somatic stimulation became flat around $\kappa \approx 0.4$, which is **20μm** away from the soma since $L_{\text{hillock}} = 10\text{μm}$ (Figure 2). In Figure S11, with a **100μm** AIS, the I_{BP} slope flattens around $\kappa \approx 0.1$, which again corresponds to a distance of roughly **20μm** from the soma since the distance in **μm** to the crossover position is $\kappa \times \ell_{\text{AIS}}$. This suggests that the threshold-lowering effect of Na_V separation for small κ (Figure 2) results from the increased proximal density of $\text{Na}_\text{V}1.6$ when the crossover is brought near to the soma —and is not due to the proximal density of $\text{Na}_\text{V}1.2$, consistent with Figure S12.

Figure S11: Somatic Stimulation with AIS lengthened to **100μm** (compare with Figure 2 in the main text where the AIS length was **25μm**): Combined effect of varying crossover location (κ) and Na_V separation (x) in the axon initial segment. The distance in **μm** to the crossover position is $\kappa \times \ell_{\text{AIS}}$. The lines have been drawn to guide the eye.

Figure S12 demonstrates that increasing κ raises the backpropagation threshold when current is injected somatodendritically (orthodromic stimulation), even when the slopes in Figure 2 are negative. Increasing

831 κ means moving the Na$_V$ crossover location away from the soma, which increases the proportion of Na$_V$1.2

832 (versus Na$_V$1.6) in the AIS; see Figure 1b.

Figure S12: Somatic Stimulation with nominal AIS length ($\ell_{\text{AIS}} = 25.0\,\mu\text{m}$). The combined effect of varying crossover location (κ) and Na$_V$ separation (x) in the axon initial segment. Increasing κ raises the backpropagation threshold. Here the abscissa is the normalized crossover position κ, instead of Na$_V$ separation (compare with Figure 2). In Figure 2, all curves converge at $x = 0$. Here, that intersection point is replaced by the $x = 0$ *line*. Notice that every $x > 0$ curve has a positive slope: the backpropagation threshold I_{BP} *increases* with κ. Increasing κ when $x > 0$ necessarily increases the ratio of Na$_V$1.2 conductance to Na$_V$1.6 conductance in the AIS (see Equation S1). It follows that concentrating Na$_V$1.2 in the proximal AIS raises the backpropagation threshold, for somatic stimulation. The lines have been drawn to guide the eye.

Figure S13: Dendritic Stimulation with nominal AIS length ($\ell_{\mathrm{AIS}} = 25.0\mu\mathrm{m}$). Current injection at the main apical dendrite yields the same qualitative behaviour as for somatic stimulation. Compare with (Figure 2). Varying the separation parameter "x" from $x = 0$ to $x = 1$, the distribution of $\mathrm{Na_V}$ channels goes from flat (homogeneous) to separated, the latter approximating the distribution observed in developing pyramidal neurons (see Figure 1a). Note that curves for all values of κ converge to a single point at $x = 0$ since κ can have no effect when the two $\mathrm{Na_V}$ subtypes are uniformly distributed along the AIS. The lines have been drawn to guide the eye.

Figure S14: Somatic Stimulation: lengthening the hillock to 30μm removes the negative slopes observed in Figure 2 and Figure S11. In all other plots, we have used $L_{\text{hillock}} = 10$μm. AIS length is $\ell_{\text{AIS}} = 25.0$μm as in all other plots unless indicated otherwise. The lines have been drawn to guide the eye.

S1.5   AIS - technical details

In our model, the density profiles of $Na_V1.2$ and $Na_V1.6$ are left- and right-handed sigmoidal functions (respectively) of normalized length s along the AIS. The proximal end of the AIS is located at $s = 0$, and the distal end is located at $s = 1$. The channel densities are expressed as maximal conductances $\bar{g}_{Na_V1.2}$ (s) and $\bar{g}_{Na_V1.6}$ (s), where the total maximal Na_V conductance $\bar{g}_{Na_V}$ is constant along the AIS:

$$\bar{g}_{Na_V} = \bar{g}_{Na_V1.2}(s) + \bar{g}_{Na_V1.6}(s) = \mathit{const.} \tag{S1}$$

The density profiles are given by

$$\begin{cases} \bar{g}_{Na_V1.2}(s) &= \dfrac{\bar{g}_{Na_V}}{2}\left(1 - x \cdot \tanh\left(\sigma(s - \kappa)\right)\right), \\[2mm] \bar{g}_{Na_V1.6}(s) &= \bar{g}_{Na_V} - \bar{g}_{Na_V1.2}(s) \\[1mm] &= \dfrac{\bar{g}_{Na_V}}{2}\left(1 + x \cdot \tanh\left(\sigma(s - \kappa)\right)\right). \end{cases} \tag{S2}$$

We chose the hyperbolic tangent function $\tanh(s)$, but other sigmoidal functions would do just as well. The parameter x controls the separation of the Na_V distribution, that is, how separated the two Na_V subtypes are. When $x = 0$, the distribution becomes flat —$Na_V1.2$ and $Na_V1.6$ are mixed uniformly along the AIS. When $x = 1$, the proximal end of the AIS contains only $Na_V1.2$, and the distal end of the AIS contains only $Na_V1.6$. The parameter σ is the reciprocal of the 'transition width' of the AIS Na_V distributions normalized by the AIS length. In all simulations shown here, $\sigma = 10.0$.

The total Na_V conductance of the AIS is proportional to AIS length ℓ since its diameter is constant

$$\bar{G}_{Na_V} = \bar{g}_{Na_V} \cdot (\text{Area of AIS}) \propto \bar{g}_{Na_V}\,\ell_{AIS}. \tag{S3}$$

The contribution to this total conductance from $Na_V1.2$ is

$$\bar{G}_{Na_V1.2} \propto \int_0^{\ell_{AIS}} d\ell' \, \bar{g}_{Na_V1.2}(\ell') = \ell_{AIS}\int_0^1 ds \, \frac{\bar{g}_{Na_V}}{2}\left(1 - x \cdot \tanh\left(\sigma(s - \kappa)\right)\right), \tag{S4}$$

$$\Rightarrow \bar{G}_{\mathrm{Na_V}1.2} \propto 1 - x \cdot \underbrace{\left(\frac{\ln \left(\cosh(\sigma) - \sinh(\sigma) \tanh(\sigma\kappa) \right)}{\sigma} \right)}_{\text{``}M\text{''}}. \tag{S5}$$

The root of the term labeled "M" in Equation S5 is $\kappa = \dfrac{1}{2}$, and the slope of M is negative: $M(\kappa < 0.5) > 0$, $M(\kappa > 0.5) < 0$. Since $M(\kappa = 0.5) = 0$, the derivative of $\bar{G}_{\mathrm{Na_V}1.2}$ (and $\bar{G}_{\mathrm{Na_V}1.6}$) with respect to x is zero when the crossover is located in the middle of the AIS, which is the standard configuration for varying $\mathrm{Na_V}$ separation. We call $\kappa = 0.5$ standard because, in this configuration, the effects on the backpropagation threshold due to varying x can not be due to changes in the total conductance of $\mathrm{Na_V}1.6$ or $\mathrm{Na_V}1.2$ in the AIS. In other words, the results of sweeping x from 0 to 1 with κ fixed at 0.5 in Figure 4, Figure 5, and Figure 2 are purely due to mixing and separating $\mathrm{Na_V}1.6$ from $\mathrm{Na_V}1.2$ in the AIS.

Since by definition $0 \leqslant \kappa \leqslant 1$ and $\sigma > 0$, the partial derivative of M with respect to κ is negative. It follows from Equation S5 that $\bar{G}_{\mathrm{Na_V}1.2}$ increases as the crossover position is moved distally. Likewise $\bar{G}_{\mathrm{Na_V}1.6}$ decreases with increasing κ.

S1.6   Voltage-gated channels

The voltage-gated sodium and potassium conductances $g_{\mathrm{Na_V}}(V,t)$ and $g_{\mathrm{K_V}}(V,t)$ in Equation 15 are modeled using HH-style kinetics [40] fitted to mammalian pyramidal cell data by [11], and then further adapted by [14] to include two $\mathrm{Na_V}$ variants (Equation S7). In the Hodgkin-Huxley model, the current density I_{Z} of ion species "Z" through voltage-gated channels of a given type is

$$I_{\mathrm{Z_V}} = \bar{g}_{\mathrm{Z_V}} m^p h^q (V - E_{\mathrm{Z}}), \tag{S6}$$

where $\bar{g}$ is the maximal conductance, $m(V,t)$ is the probability for an *activation* gate to be open, p is the number of *activation* gates per channel, $h(V,t)$ is the *availability* (probability that the channel is *not inactivated*), and q is the number of inactivation gates per channel. $\mathrm{Na_V}$ channels are modeled as having three *activation* gates ($p = 3$) and a single inactivation gate ($q = 1$) so that $g_{\mathrm{Na_V}} \propto m^3 h$. Likewise, $\mathrm{K_V}$ channels have a single *activation* gate and no inactivation ($g_{\mathrm{K_V}} \propto n$). The gating variables m, h, and n evolve according to Equations 6, 7, and 8. Since the cell features two $\mathrm{Na_V}$ subtypes ($\mathrm{Na_V}1.2$ and $\mathrm{Na_V}1.6$), the model computes two sets of sodium *activation* and *availability* variables. The current density

870 I_{Na} through the $\mathrm{Na_V}$ channels is then

$$I_{\mathrm{Na_V}} = \left(\underbrace{\bar{g}_{\mathrm{Na_V 1.2}} (m^{\mathrm{Na_V 1.2}})^3 h^{\mathrm{Na_V 1.2}}}_{g_{\mathrm{Na_V 1.2}}} + \underbrace{\bar{g}_{\mathrm{Na_V 1.6}} (m^{\mathrm{Na_V 1.6}})^3 h^{\mathrm{Na_V 1.6}}}_{g_{\mathrm{Na_V 1.6}}} \right) (V - E_{\mathrm{Na^+}}), \qquad \text{(S7)}$$

871 where $g_{\mathrm{Na_V 1.2}} + g_{\mathrm{Na_V 1.6}} = g_{\mathrm{Na_V}}$ in Equation 15.

872 Figure S15 plots the voltage-dependent kinetics of $m^{\mathrm{Na_V 1.2}}$, $h^{\mathrm{Na_V 1.2}}$, $m^{\mathrm{Na_V 1.6}}$ and $h^{\mathrm{Na_V 1.6}}$. The steady-

873 state *activation* and *availability* functions and their voltage-sensitive time constants were implemented

874 using the parameters provided in [14] and in model code published by [24]. We further modified the

875 channel models to allow shift-clamping; see Section 2.5 and Section 4.2.

(a) Gating variables' steady-states   (b) And their voltage-sensitive time constants

Figure S15: Gating properties of the voltage-gated sodium and potassium channels that are implemented in this model. Dotted vertical lines indicate the resting potential V_{rest}. (**a**) Steady-state *activation* and *availability* curves for $\mathrm{Na_V}1.2$ and $\mathrm{Na_V}1.6$, and steady-state $\mathrm{K_V}$ *activation*. (**b**) Voltage-sensitive time constants of $\mathrm{Na_V}1.2$, $\mathrm{Na_V}1.6$, and $\mathrm{K_V}$. $\mathrm{Na_V}1.2$ is *right-shift*ed by an amount V_{RS} relative to $\mathrm{Na_V}1.6$ (defined in Section S1.6.1). In this model, $V_{\mathrm{RS}} = 13.0\mathrm{mV}$; also called the 'nominal *right-shift*' of $\mathrm{Na_V}1.2$. V_{RS} is **indicated by arrows** (small $\bullet\!\!\rightarrow$) in the plots of $\mathrm{Na_V}$ steady-states (**a**) and time constants (**b**) above.

V_{RS} is indicated by arrows (small $\bullet\!\!\rightarrow$) in the plots of $\mathrm{Na_V}$ steady-states (Figure S15a) and time constants

(Figure S15b).

The *right-shift* of Na$_\text{V}$1.2 (defined mathematically in Section S1.6.1) is easiest to observe in the top

two plots of Figure S15a. V_RS is indicated by arrows (small •—→). Steady-state *activation* $\left(m_\infty^{\text{Na}_\text{V}1.2}(V)\right)^3$

and *availability* $h_\infty^{\text{Na}_\text{V}1.2}(V)$ curves of Na$_\text{V}$1.2 are plotted as solid green lines, and dashed blue lines are

the corresponding curves for Na$_\text{V}$1.6. The voltage separating the two Na$_\text{V}$ subtypes' *activation* curves is

approximately the nominal *right-shift*, V_RS; however, it varies with position, since the gating variables of

Na$_\text{V}$ *activation* ($m^{\text{Na}_\text{V}1.2}$, $m^{\text{Na}_\text{V}1.6}$) have different slopes [14]. However, the *availability* curves are easier

to compare: in this model, $h_\infty^{\text{Na}_\text{V}1.2}(V)$ is shifted exactly $V_\text{RS} = 13.0\text{mV}$ to the right of $h_\infty^{\text{Na}_\text{V}1.6}(V)$. The

right-shift of Na$_\text{V}$1.2 is also visible in the voltage-sensitive time constants (Figure S15b).

S1.6.1   Defining V_RS: the *right-shift* of Na$_\text{V}$1.2

887   V_RS is a parameter in this model representing the experimentally measured depolarizing shift in the voltage

888   dependence of Na$_\text{V}$1.2 *activation* and inactivation kinetics, relative to Na$_\text{V}$1.6 kinetics. Because V_RS is

889   empirical, it is fixed in this paper.

We define the Na$_\text{V}$1.6 half-*activation* voltage $V_{1/2}^{\text{Na}_\text{V}1.6}$ as the voltage at which a single Na$_\text{V}$1.6 *activation*

gate (randomly selected from an ensemble of gates held at $V = V_{1/2}^{\text{Na}_\text{V}1.6}$) has a **50%** chance of being in the

open state:

$$m_\infty^{\text{Na}_\text{V}1.6}(V_{1/2}^{\text{Na}_\text{V}1.6}) \stackrel{\text{def}}{=} \frac{1}{2}.$$

890   Although the kinetics of Na$_\text{V}$1.2 differ from Na$_\text{V}$1.6 kinetics in ways *other than right-shift*, we can now use

891   $V_{1/2}^{\text{Na}_\text{V}1.6}$ to define V_RS as the voltage that satisfies

$$\boxed{m_\infty^{\text{Na}_\text{V}1.2}(V_{1/2}^{\text{Na}_\text{V}1.6} + V_\text{RS}) = m_\infty^{\text{Na}_\text{V}1.6}(V_{1/2}^{\text{Na}_\text{V}1.6}) = \frac{1}{2}}. \tag{S8}$$

892   Note that $V_{1/2}^{\text{Na}_\text{V}1.6}$ and V_RS are unique since m_∞ is monotonically increasing. Equation S8 also contains the

893   half-*activation* voltage for Na$_\text{V}$1.2,

$$\left(V_{1/2}^{\text{Na}_\text{V}1.6} + V_\text{RS}\right) = V_{1/2}^{\text{Na}_\text{V}1.2}, \tag{S9}$$

which is depolarized or "*right-shift*ed" by an amount V_RS relative to Na$_\text{V}$1.6 (see Figure S15).

To simulate alterations to Na$_\text{V}$1.2 *right-shift* in our shift-clamping method, we use another parameter

called ΔV_RS, which is not based on experiment. Although the Na$_\text{V}$1.2 *right-shift* is not a high precision

measurement ($V_{\mathrm{RS}} \sim 10-15\mathrm{mV}$), the *parameter* V_{RS} is kept fixed in our model for conceptual purposes: we

find it helpful to distinguish empirical parameters (like V_{RS}) from exploratory parameters that intentionally

deviate from experiment (like ΔV_{RS}). In fact, we use ΔV_{RS} to selectively change the model's Na$_{\mathrm{V}}$ kinetics

to explain the effects of Na$_{\mathrm{V}}$ distribution on excitability in terms of the lengthwise distribution of gating

properties (see Section 2.5 and Section 4.2).

S1.6.2   Notation: $V_{\mathbf{RS}}$, $\Delta V_{\mathbf{RS}}$

In our notation, V_{RS} is *not written explicitly* in the argument of Na$_{\mathrm{V}}$1.2 gating variables or their time constants. Instead, we write

$$\tau_h^{\mathrm{Na_V}1.6}(V),\ \tau_h^{\mathrm{Na_V}1.2}(V),\ m_\infty^{\mathrm{Na_V}1.6}(V),\ m_\infty^{\mathrm{Na_V}1.2}(V),\ \text{et cetera,}$$

903 and let the superscript "$^{\mathrm{Na_V}1.2}$" indicate that $\tau_h^{\mathrm{Na_V}1.2}$ is *right-shift*ed relative to $\tau_h^{\mathrm{Na_V}1.6}$, from the fact that

904 Na$_{\mathrm{V}}$1.2 channels are *right-shift*ed in this model.

905 However, the parameter ΔV_{RS} *is* written explicitly in the argument when we model the effects of

906 modifying the *right-shift* (Figure 6: shift-clamping). For example, when applying $\Delta V_{\mathrm{RS}} \neq 0$ to the *selected*

907 gating properties $\tau_h^{\mathrm{Na_V}1.2}$ and $m_\infty^{\mathrm{Na_V}1.2}$, we would write

$$\begin{cases} \tau_h^{\mathrm{Na_V}1.2} = \tau_h^{\mathrm{Na_V}1.2}(V - \Delta V_{\mathrm{RS}}) \\[2mm] h_\infty^{\mathrm{Na_V}1.2} = h_\infty^{\mathrm{Na_V}1.2}(V) \\[2mm] \tau_m^{\mathrm{Na_V}1.2} = \tau_m^{\mathrm{Na_V}1.2}(V) \\[2mm] m_\infty^{\mathrm{Na_V}1.2} = m_\infty^{\mathrm{Na_V}1.2}(V - \Delta V_{\mathrm{RS}}). \end{cases} \tag{S10}$$

908 Using this notation, positive values of ΔV_{RS} will shift kinetic curves (gating properties) to the right in

909 Figure S15 (depolarizing shift), and negative ΔV_{RS} produces a hyperpolarizing shift.

S1.6.3   Space plots of Na$_{\mathbf{V}}$ kinetics along the AIS — steady-state

911 The distribution of Na$_{\mathrm{V}}$1.2 and Na$_{\mathrm{V}}$1.6 in the AIS creates a lengthwise distribution of gating properties.

912 Proximal Na$_{\mathrm{V}}$1.2 increases local steady-state *availability*, owing to these channels' *right-shift* (V_{RS}). In

913   Figure S16a we visualize this effect using $\mathcal{H}(s)$: the net *availability* of $\mathrm{Na_V}$s ($\mathcal{H}$) as a function of position

914   (s), computed by weighting $h^{\mathrm{Na_V1.2}}$ and $h^{\mathrm{Na_V1.6}}$ according to their respective local $\mathrm{Na_V}$ channel densities:

$$\mathcal{H}(s,t) = \frac{\bar{g}_{\mathrm{Na_V1.2}}(s)h^{\mathrm{Na_V1.2}}(s,t) + \bar{g}_{\mathrm{Na_V1.6}}(s)h^{\mathrm{Na_V1.6}}(s,t)}{\bar{g}_{\mathrm{Na_V1.2}}(s) + \bar{g}_{\mathrm{Na_V1.6}}(s)}. \tag{S11}$$

915   An effective local $\mathrm{Na_V}$ time constant of *availability* ($\mathcal{T}$) can be computed from $\tau_h^{\mathrm{Na_V1.2}}$ and $\tau_h^{\mathrm{Na_V1.6}}$ as

$$\mathcal{T}(s,t) = \frac{\bar{g}_{\mathrm{Na_V1.2}}(s)\tau_h^{\mathrm{Na_V1.2}}(s,t) + \bar{g}_{\mathrm{Na_V1.6}}(s)\tau_h^{\mathrm{Na_V1.6}}(s,t)}{\bar{g}_{\mathrm{Na_V1.2}}(s) + \bar{g}_{\mathrm{Na_V1.6}}(s)}. \tag{S12}$$

916   Above, we have abbreviated

$$f(V(s,t),t) = f(s,t) \text{ for } f = h^{\mathrm{Na_V1.2}}, h^{\mathrm{Na_V1.6}}, \tau_h^{\mathrm{Na_V1.2}}, \tau_h^{\mathrm{Na_V1.6}}. \tag{S13}$$

917   In Figure S16b we have selectively disabled the *right-shift* of $\tau_h^{\mathrm{Na_V1.2}}$ by setting $\Delta V_{\mathrm{RS}} = -V_{\mathrm{RS}} = -13.0\mathrm{mV}$

918   in Equation 2, which leaves the *right-shift* of steady-state *availability* unchanged.

(a) Solid green curve: nominal $Na_V1.2$ *right-shift*. Travelling from left to right across the AIS, $Na_V1.6$ overtakes $Na_V1.2$ as a share of the total local Na_V density. The accompanying change in Na_V *right-shift* causes $\mathcal{H}(s)$ to drop from ≈ 0.6 at the soma and proximal AIS, down to ≈ 0.2 at the distal AIS and axon. Dashed black curve: the *right-shift* of $\tau_h^{\mathrm{Na_V1.2}}$ has been selectively disabled without altering $h_\infty^{\mathrm{Na_V1.2}}$, and thereby $\mathcal{H}$ is also unaffected. See (b) to the right as well as Equation 2.

(b) Solid green curve: nominal $Na_V1.2$ *right-shift*. Where $Na_V1.6$ overtakes $Na_V1.2$ as a share of the total local Na_V density, $\mathcal{T}(s)$ increases from $\approx 6\text{ms}$ to $\approx 8\text{ms}$. Dashed black curve: *right-shift* of $\tau_h^{\mathrm{Na_V1.2}}$ selectively disabled by setting $\Delta V_{\mathrm{RS}} = -V_{\mathrm{RS}}$ in Equation 2. The effective time constant of Na_V *availability* $\mathcal{T}(s)$ is now uniform along the AIS. The abrupt transition in $\mathcal{T}$ at the AIS-hillock interface —instead of the smooth transition along the AIS in the green curve— is due to the *right-shift* of $\tau_h^{\mathrm{Na_V1.2}}(V)$ being selectively disabled —see Equation S12. The *right-shift* of $h_\infty^{\mathrm{Na_V1.2}}(V)$ has not been altered (see Equation S11), and the corresponding $\mathcal{H}$ (dashed black) curve in (a) is unchanged —hence the term "selective".

Figure S16: The effect of $Na_V1.2$ *right-shift* on local Na_V *availability* along the cell is visible in space plots of steady-state total *availability* $\mathcal{H}(s)$ (a) and total time constant $\mathcal{T}(s)$ (b) at $V = V_{\mathrm{rest}}$. See Equation S11 and Equation S12, respectively.

S1.7   Diffusion coefficients

Diffusion coefficients for Na^+, K^+, and Cl^- in water at 25.0 ℃ are provided by [46] :

$$
\begin{cases}
D_{Na^+} = 1.334 \times 10^{-9} \dfrac{m^2}{s} \\[2mm]
D_{K^+} = 1.957 \times 10^{-9} \dfrac{m^2}{s} \\[2mm]
D_{Cl^-} = 2.032 \times 10^{-9} \dfrac{m^2}{s}.
\end{cases}
\tag{S14}
$$

Our simulations are done at a warmer temperature, so these coefficients need to be adjusted. We make the adjustment using the Stokes-Einstein equation

$$
D = \frac{k_B T}{\zeta(T)} = \frac{k_B T}{6\pi r \eta(T)} \; ;
\tag{S15}
$$

where k_B is Boltzmann's constant, T is the temperature (Kelvins K), and ζ is called the drag coefficient. ζ is given by the ion's radius r and the viscosity $\eta(T)$ of the medium (liquid water), which depends on temperature. Hence the ratio of diffusion coefficients for ion species Z at T_2 and T_1 is

$$
\frac{D_Z(T_2)}{D_Z(T_1)} = \left(\frac{T_2}{T_1}\right)\left(\frac{\eta(T_1)}{\eta(T_2)}\right),
\tag{S16}
$$

with T_2 and T_1 converted to K. The reference values provided by [46] are measured at 298.15K (25.0℃), and the simulation temperature is 310.15K (37.0℃). Assuming the viscosity of water, we have $\eta(T_1) \cong$ 0.89 mPa s and $\eta(T_2) \cong$ 0.691 mPa s. Substituting these η's into Equation S16 gives for each ionic species Z

$$
\underbrace{D_Z(310.15K)}_{37.0℃} \cong 1.34 \times \underbrace{D_Z(298.15K)}_{25.0℃},
\tag{S17}
$$

which yields the temperature-adjusted diffusion coefficients

$$
\begin{cases}
D_{Na^+} = 1.79 \times 10^{-9} \dfrac{m^2}{s} \\[2mm]
D_{K^+} = 2.62 \times 10^{-9} \dfrac{m^2}{s} \\[2mm]
D_{Cl^-} = 2.72 \times 10^{-9} \dfrac{m^2}{s}.
\end{cases}
\tag{S18}
$$

S1.8   Tables of parameters

In the following tables, we compare our model to previous models on which it is based ([11], [24], [14]). At different locations in the cell, we list key parameter values from these papers alongside our own. We also include certain measurements (membrane potential, ion concentrations, Nernst potentials) taken from our model at each location once the cell has equilibrated.

The following symbols are used in the tables: (Units are given in the tables.)

"×"   This symbol appears when a parameter is not featured in the model corresponding to a given column.

$V_{\mathbf{rest}}$ Resting potential. The transmembrane voltage of the model neuron at steady-state with no injected current.

$V_{\mathbf{m}}^{\mathbf{location}}$ Transmembrane voltage at 'location'. In our model, the steady-state transmembrane voltage is actively maintained everywhere by $\mathrm{Na^+/K^+}$-pumps and longitudinal diffusion, which control the explicit intracellular and extracellular ion concentrations. As such, the tabulated values are *recorded* from the model, not parameters per se. In the other models listed, V_{m} is identical to V_{rest}.

$R_{\mathbf{axial}}$ Axial resistance. The resistance to axial current flow across a compartment is R_{axial} multiplied by the compartment length, divided by the compartment's cross-sectional area.

$D_{\mathbf{ion}}$ Diffusion coefficient of the specified ion in water at 37℃.

$T_{\mathbf{ref}}$ Reference temperature of experimentally developed channel properties used in the models. Past modelling, on which this paper is based, used temperature factors (described below) to adjust channel densities and speed up channel kinetics to warmer temperatures.

T Simulation temperature.

$Q_{\bar{g}_{\mathbf{V}}}^{\mathbf{Mainen}} = Q_{10,\bar{g}_{\mathbf{V}}}^{(T-T_{\mathbf{ref}})/10℃}$ To adjust for a warmer simulation temperature of $T = 37℃$ [24] scales up the maximal voltage-gated conductances, which were originally developed at $T = 23℃$ ([11]), by a factor which we denote $Q_{\mathrm{Mainen}}^{\bar{g}_{\mathrm{V}}}$. The authors warn in their model code that this scaling is valid only at 37℃ and state that their program is not designed to model other temperatures. This internal temperature scaling can accidentally obscure parameter settings when one attempts to borrow parameters separately from the past code or from later papers that reuse these channel models. For this reason, we

have removed the temperature scaling from our own model code by setting our reference temperature equal to the simulation temperature, which sets $Q^{\bar{g}_V}_{\text{Mainen}} = 1$.

$\bar{g}^{\text{location}}_{\text{Na}_V \cdot \text{Total}}$ Total combined maximal voltage-gated conductance density of $\text{Na}_V 1.2$ and $\text{Na}_V 1.6$ at the specified 'location' in the cell (see Equation S1). The location can be an entire Section if the membrane properties are uniform (in NEURON, Sections consist of multiple compartments). For example, this model has uniform somatodendritic channel densities, so 'soma' is sufficient to specify those parameters.

$\bar{g}^{\text{location}}_{\text{K}_V \cdot \text{Total}}$ Maximal voltage-gated K^+ conductance density at the specified 'location'.

C_{m} Membrane capacitance per unit area. Applies everywhere except at internodes.

$C^{\text{myelin}}_{\text{m}}$ Membrane capacitance of myelinated internodes.

L_{Section} Length of the specified 'Section' (soma, hillock, AIS, etc.)

$d^{\text{position within Section}}_{\text{Section}}$ Diameter at a given normalized position ($0 \leqslant s \leqslant 1$) within the specified Section (soma, hillock, AIS, etc.). The position is not specified when the diameter is uniform.

$R^{\text{Section}}_{\text{Passive}}$ Membrane resistivity in 'Section'.

$g^{\text{Section}}_{\text{Passive}}$ Passive generic transmembrane leak conductance density in 'Section'.

$g^{\text{Section}}_{\text{Ion, leak}}$ Specific leak conductance density of 'Ion' in 'Section'.

$I^{\text{Section}}_{\text{MaxPump}}$ Maximum Na^+/K^+-pump current density in 'Section'.

$E^{\text{Section}}_{\text{current type}}$ Nernst Potential (reversal potential) of transmembrane current 'current type' (e.g. 'leak') in 'Section' (e.g. 'soma').

$[\text{Ion}]^{\text{Section}}_{\text{in/out}}$ Intracellular ('in') or Extracellular ('out') concentration of 'Ion' at 'Section', with the neuron at steady-state. Because these concentrations are maintained by Na^+/K^+-pumps and longitudinal diffusion in our model, the concentrations tabulated here are measurements *recorded* from the simulation at steady-state, rather than being fixed parameters.

980 **ranvier0, myelin0:** In our model, there are 15 nodes of Ranvier and 16 myelinated internodes. The

981   Section named 'ranvier0' is the first node of Ranvier. And 'myelin0' is the first myelinated internode

982   of the axon, located between the distal end of the AIS (or the distal end of the bare axon when that

983   is included) and the proximal end of ranvier0.

Type	Parameter Name	OURMODEL	MAINEN95	MAINEN96	HU2009	UNITS
Global						
	V_{rest}	-70.0	-70.0	-70.0	-70.0	mV
	R_{axial}	150	200	150	150	$\Omega \cdot \text{cm}$
	D_{Cl^-}	2.72	$\times$	$\times$	$\times$	$10^{-9}\dfrac{\text{m}^2}{\text{s}}$
	D_{Na^+}	1.79	$\times$	$\times$	$\times$	$10^{-9}\dfrac{\text{m}^2}{\text{s}}$
	D_{K^+}	2.62	$\times$	$\times$	$\times$	$10^{-9}\dfrac{\text{m}^2}{\text{s}}$
	T_{ref}	37.0	23.0	23.0	23.0	°C
	T	37.0	23.0	37.0	37.0	°C
	$Q_{\bar{g}_{\text{V}}}^{\text{Mainen}} = Q_{10,\bar{g}_{\text{V}}}^{(T-T_{\text{ref}})/10°C}$	1.0	1.0	3.21	3.21	dimensionless
	C_{m}	0.75	0.75	0.75	1.0	$\dfrac{\mu F}{\text{cm}^2}$
	$C_{\text{m}}^{\text{myelin}}$	0.02	0.04	0.02	0.02	$\dfrac{\mu F}{\text{cm}^2}$

Geometry

	OurModel	Mainen95	Mainen96	Hu2009	
L_{soma}	30.0	25.8	30.0	30.0	µm
L_{hillock}	10.0	10.0	10.0	10.0	µm
L_{AIS}	25.0	15.0	15.0	50.0	µm
$L_{\mathrm{bare\cdot axon}}$	400	×	×	400	µm
$d_{\mathrm{soma}}^{0.5}$	19.38	15.2	19.0	19.0	µm
$d_{\mathrm{soma}}^{1.0}$	8.62	15.2	8.6	8.6	µm
$d_{\mathrm{hillock}}^{0.0}$	8.62	4.0	4.0	3.8	µm
$d_{\mathrm{hillock}}^{1.0}$	1.22	1.0	1.0	2.4	µm
d_{AIS}	1.22	1.0	1.0	1.22	µm
$d_{\mathrm{bare\cdot axon}}$	1.22	×	×	1.02	µm

section	Parameter Name	OurModel	Mainen95	Mainen96	Hu2009	units
soma						
	$\bar{g}_{\mathrm{Na_V\cdot Total}}^{\mathrm{soma}}$	7.53×10^{-2}	0.003	0.002	0.008	$\frac{\text{℧}}{\mathrm{cm}^2}$
	$\bar{g}_{\mathrm{Na_V\cdot Total}}^{\mathrm{soma}} \times Q_{\bar{g}_{\mathrm{V}}}^{\mathrm{Mainen}}$	7.53×10^{-2}	3.00×10^{-3}	6.42×10^{-3}	2.57×10^{-2}	$\frac{\text{℧}}{\mathrm{cm}^2}$

$\bar{g}_{\mathrm{K_V}}^{\mathrm{soma}}$	2.26×10^{-2}	0.01	0.02	0.002	$\dfrac{\text{℧}}{\text{cm}^2}$
$\bar{g}_{\mathrm{K_V}}^{\mathrm{soma}} \times Q_{\bar{g}_\mathrm{V}}^{\mathrm{Mainen}}$	2.26×10^{-2}	1.00×10^{-2}	6.42×10^{-2}	6.42×10^{-3}	$\dfrac{\text{℧}}{\text{cm}^2}$
$R_{\mathrm{Passive}}^{\mathrm{soma}}$	2.39×10^{3}	4.00×10^{4}	3.00×10^{4}	3.00×10^{4}	$\Omega \cdot \text{cm}^2$
$g_{\mathrm{Passive}}^{\mathrm{soma}}$	4.19×10^{-4}	2.50×10^{-5}	3.33×10^{-5}	3.33×10^{-5}	$\dfrac{\text{℧}}{\text{cm}^2}$
$g_{\mathrm{Cl^-,\ leak}}^{\mathrm{soma}}$	6.27×10^{-5}	$\times$	$\times$	$\times$	$\dfrac{\text{℧}}{\text{cm}^2}$
$g_{\mathrm{Na^+,\ leak}}^{\mathrm{soma}}$	6.68×10^{-5}	$\times$	$\times$	$\times$	$\dfrac{\text{℧}}{\text{cm}^2}$
$g_{\mathrm{K^+,\ leak}}^{\mathrm{soma}}$	2.90×10^{-4}	$\times$	$\times$	$\times$	$\dfrac{\text{℧}}{\text{cm}^2}$
$I_{\mathrm{MaxPump}}^{\mathrm{soma}}$	3.99×10^{-2}	$\times$	$\times$	$\times$	$\dfrac{\text{mA}}{\text{cm}^2}$
$V_{\mathrm{m}}^{\mathrm{soma}}$	-70.0	-70.0	-70.0	-70.0	mV
$E_{\mathrm{leak}}^{\mathrm{soma}}$	$\times$	-70.0	-70.0	-70.0	mV
$E_{\mathrm{Cl}}^{\mathrm{soma}}$	-70.0	$\times$	$\times$	$\times$	mV
$E_{\mathrm{Na}}^{\mathrm{soma}}$	60.0	60.0	50.0	60.0	mV
$E_{\mathrm{K}}^{\mathrm{soma}}$	-90.0	-90.0	-90.0	-90.0	mV
$[\mathrm{Cl^-}]_{\mathrm{in}}^{\mathrm{soma}}$	11.0	$\times$	$\times$	$\times$	mM
$[\mathrm{Cl^-}]_{\mathrm{out}}^{\mathrm{soma}}$	151.0	$\times$	$\times$	$\times$	mM

section	Parameter Name	OurModel	Mainen95	Mainen96	Hu2009	units
	$[\text{Na}^+]_{\text{in}}^{\text{soma}}$	15.0	×	×	×	mM
	$[\text{Na}^+]_{\text{out}}^{\text{soma}}$	141.6	×	×	×	mM
	$[\text{K}^+]_{\text{in}}^{\text{soma}}$	140.0	×	×	×	mM
	$[\text{K}^+]_{\text{out}}^{\text{soma}}$	4.8	×	×	×	mM

section	Parameter Name	OurModel	Mainen95	Mainen96	Hu2009	units
AIS						
	$\bar{g}_{\text{Na}_\text{V}\cdot\text{Total}}^{\text{AIS}}$	1.505	3.0	3.0	0.32	$\frac{\text{℧}}{\text{cm}^2}$
	$\bar{g}_{\text{Na}_\text{V}\cdot\text{Total}}^{\text{AIS}} \times Q_{\bar{g}_\text{V}}^{\text{Mainen}}$	1.505	3.0	9.628	1.027	$\frac{\text{℧}}{\text{cm}^2}$
	$\bar{g}_{\text{K}_\text{V}}^{\text{AIS}}$	4.52×10^{-1}	×	0.2	0.1	$\frac{\text{℧}}{\text{cm}^2}$
	$\bar{g}_{\text{K}_\text{V}}^{\text{AIS}} \times Q_{\bar{g}_\text{V}}^{\text{Mainen}}$	4.52×10^{-1}	×	6.42×10^{-1}	3.21×10^{-1}	$\frac{\text{℧}}{\text{cm}^2}$
	$R_{\text{Passive}}^{\text{AIS}}$	4.77×10^{1}	5.00×10^{1}	5.00×10^{1}	5.00×10^{1}	$\Omega \cdot \text{cm}^2$
	$g_{\text{Passive}}^{\text{AIS}}$	2.10×10^{-2}	2.00×10^{-2}	2.00×10^{-2}	2.00×10^{-2}	$\frac{\text{℧}}{\text{cm}^2}$
	$g_{\text{Cl}^-,\text{ leak}}^{\text{AIS}}$	3.14×10^{-3}	×	×	×	$\frac{\text{℧}}{\text{cm}^2}$
	$g_{\text{Na}^+,\text{ leak}}^{\text{AIS}}$	3.34×10^{-3}	×	×	×	$\frac{\text{℧}}{\text{cm}^2}$

section	Parameter Name	OurModel	Mainen95	Mainen96	Hu2009	units
	$g_{\text{K}^+,\text{ leak}}^{\text{AIS}}$	1.45×10^{-2}	$\times$	$\times$	$\times$	$\dfrac{\mho}{\text{cm}^2}$
	$I_{\text{MaxPump}}^{\text{AIS}}$	1.995	$\times$	$\times$	$\times$	$\dfrac{\text{mA}}{\text{cm}^2}$
	$V_{\text{m}}^{\text{AIS}}$	-69.9	-70.0	-70.0	-70.0	mV
	$E_{\text{leak}}^{\text{AIS}}$	$\times$	-70.0	-70.0	-70.0	mV
	$E_{\text{Cl}}^{\text{AIS}}$	-70.0	$\times$	$\times$	$\times$	mV
	$E_{\text{Na}}^{\text{AIS}}$	59.9	60.0	50.0	60.0	mV
	$E_{\text{K}}^{\text{AIS}}$	-90.0	-90.0	-90.0	-90.0	mV
	$[\text{Cl}^-]_{\text{in}}^{\text{AIS}}$	11.0	$\times$	$\times$	$\times$	mM
	$[\text{Cl}^-]_{\text{out}}^{\text{AIS}}$	151.0	$\times$	$\times$	$\times$	mM
	$[\text{Na}^+]_{\text{in}}^{\text{AIS}}$	15.1	$\times$	$\times$	$\times$	mM
	$[\text{Na}^+]_{\text{out}}^{\text{AIS}}$	141.6	$\times$	$\times$	$\times$	mM
	$[\text{K}^+]_{\text{in}}^{\text{AIS}}$	139.9	$\times$	$\times$	$\times$	mM
	$[\text{K}^+]_{\text{out}}^{\text{AIS}}$	4.8	$\times$	$\times$	$\times$	mM

myelin0

$\bar{g}_{\mathrm{Na_V \cdot Total}}^{\mathrm{myelin0}}$	1.61×10^{-2}	0.003	$\times$	0.002	$\dfrac{\mho}{\mathrm{cm}^2}$
$\bar{g}_{\mathrm{Na_V \cdot Total}}^{\mathrm{myelin0}} \times Q_{\bar{g}_V}^{\mathrm{Mainen}}$	1.61×10^{-2}	3.00×10^{-3}	$\times$	6.42×10^{-3}	$\dfrac{\mho}{\mathrm{cm}^2}$
$\bar{g}_{\mathrm{K_V}}^{\mathrm{myelin0}}$	4.82×10^{-3}	$\times$	$\times$	$\times$	$\dfrac{\mho}{\mathrm{cm}^2}$
$\bar{g}_{\mathrm{K_V}}^{\mathrm{myelin0}} \times Q_{\bar{g}_V}^{\mathrm{Mainen}}$	4.82×10^{-3}	$\times$	$\times$	$\times$	$\dfrac{\mho}{\mathrm{cm}^2}$
$R_{\mathrm{Passive}}^{\mathrm{myelin0}}$	1.12×10^{4}	4.00×10^{4}	3.00×10^{4}	3.00×10^{4}	$\Omega \cdot \mathrm{cm}^2$
$g_{\mathrm{Passive}}^{\mathrm{myelin0}}$	8.94×10^{-5}	2.50×10^{-5}	3.33×10^{-5}	3.33×10^{-5}	$\dfrac{\mho}{\mathrm{cm}^2}$
$g_{\mathrm{Cl^-,\ leak}}^{\mathrm{myelin0}}$	1.34×10^{-5}	$\times$	$\times$	$\times$	$\dfrac{\mho}{\mathrm{cm}^2}$
$g_{\mathrm{Na^+,\ leak}}^{\mathrm{myelin0}}$	1.43×10^{-5}	$\times$	$\times$	$\times$	$\dfrac{\mho}{\mathrm{cm}^2}$
$g_{\mathrm{K^+,\ leak}}^{\mathrm{myelin0}}$	6.18×10^{-5}	$\times$	$\times$	$\times$	$\dfrac{\mho}{\mathrm{cm}^2}$
$I_{\mathrm{MaxPump}}^{\mathrm{myelin0}}$	8.51×10^{-3}	$\times$	$\times$	$\times$	$\dfrac{\mathrm{mA}}{\mathrm{cm}^2}$
$V_{\mathrm{m}}^{\mathrm{myelin0}}$	-69.5	-70.0	-70.0	-70.0	mV
$E_{\mathrm{leak}}^{\mathrm{myelin0}}$	$\times$	-70.0	-70.0	-70.0	mV
$E_{\mathrm{Cl}}^{\mathrm{myelin0}}$	-70.0	$\times$	$\times$	$\times$	mV
$E_{\mathrm{Na}}^{\mathrm{myelin0}}$	60.0	60.0	50.0	60.0	mV
$E_{\mathrm{K}}^{\mathrm{myelin0}}$	-90.0	-90.0	-90.0	-90.0	mV

section	Parameter Name	OurModel	Mainen95	Mainen96	Hu2009	units
	$[\text{Cl}^-]_{\text{in}}^{\text{myelin0}}$	11.0	×	×	×	mM
	$[\text{Cl}^-]_{\text{out}}^{\text{myelin0}}$	151.0	×	×	×	mM
	$[\text{Na}^+]_{\text{in}}^{\text{myelin0}}$	15.0	×	×	×	mM
	$[\text{Na}^+]_{\text{out}}^{\text{myelin0}}$	141.6	×	×	×	mM
	$[\text{K}^+]_{\text{in}}^{\text{myelin0}}$	140.0	×	×	×	mM
	$[\text{K}^+]_{\text{out}}^{\text{myelin0}}$	4.8	×	×	×	mM

section	Parameter Name	OurModel	Mainen95	Mainen96	Hu2009	units

ranvier0

section	Parameter Name	OurModel	Mainen95	Mainen96	Hu2009	units
	$\bar{g}_{\text{Na}_\text{V}\cdot\text{Total}}^{\text{ranvier0}}$	8.03×10^{-1}	3.0	3.0	0.16	$\frac{\text{℧}}{\text{cm}^2}$
	$\bar{g}_{\text{Na}_\text{V}\cdot\text{Total}}^{\text{ranvier0}} \times Q_{\bar{g}_\text{V}}^{\text{Mainen}}$	8.03×10^{-1}	3.0	9.628	5.13×10^{-1}	$\frac{\text{℧}}{\text{cm}^2}$
	$\bar{g}_{\text{K}_\text{V}}^{\text{ranvier0}}$	2.41×10^{-1}	×	×	×	$\frac{\text{℧}}{\text{cm}^2}$
	$\bar{g}_{\text{K}_\text{V}}^{\text{ranvier0}} \times Q_{\bar{g}_\text{V}}^{\text{Mainen}}$	2.41×10^{-1}	×	×	×	$\frac{\text{℧}}{\text{cm}^2}$
	$R_{\text{Passive}}^{\text{ranvier0}}$	2.24×10^2	5.00×10^1	5.00×10^1	5.00×10^1	$\Omega \cdot \text{cm}^2$
	$g_{\text{Passive}}^{\text{ranvier0}}$	4.47×10^{-3}	2.00×10^{-2}	2.00×10^{-2}	2.00×10^{-2}	$\frac{\text{℧}}{\text{cm}^2}$

$g_{\mathrm{Cl^-,\ leak}}^{\mathrm{ranvier0}}$	6.69×10^{-4}	$\times$	$\times$	$\times$	$\dfrac{\mho}{\mathrm{cm^2}}$
$g_{\mathrm{Na^+,\ leak}}^{\mathrm{ranvier0}}$	7.13×10^{-4}	$\times$	$\times$	$\times$	$\dfrac{\mho}{\mathrm{cm^2}}$
$g_{\mathrm{K^+,\ leak}}^{\mathrm{ranvier0}}$	3.09×10^{-3}	$\times$	$\times$	$\times$	$\dfrac{\mho}{\mathrm{cm^2}}$
$I_{\mathrm{MaxPump}}^{\mathrm{ranvier0}}$	4.26×10^{-1}	$\times$	$\times$	$\times$	$\dfrac{\mathrm{mA}}{\mathrm{cm^2}}$
$V_{\mathrm{m}}^{\mathrm{ranvier0}}$	-69.4	-70.0	-70.0	-70.0	mV
$E_{\mathrm{leak}}^{\mathrm{ranvier0}}$	$\times$	-70.0	-70.0	-70.0	mV
$E_{\mathrm{Cl}}^{\mathrm{ranvier0}}$	-70.0	$\times$	$\times$	$\times$	mV
$E_{\mathrm{Na}}^{\mathrm{ranvier0}}$	60.0	60.0	50.0	60.0	mV
$E_{\mathrm{K}}^{\mathrm{ranvier0}}$	-90.0	-90.0	-90.0	-90.0	mV
$[\mathrm{Cl^-}]_{\mathrm{in}}^{\mathrm{ranvier0}}$	11.0	$\times$	$\times$	$\times$	mM
$[\mathrm{Cl^-}]_{\mathrm{out}}^{\mathrm{ranvier0}}$	151.0	$\times$	$\times$	$\times$	mM
$[\mathrm{Na^+}]_{\mathrm{in}}^{\mathrm{ranvier0}}$	15.0	$\times$	$\times$	$\times$	mM
$[\mathrm{Na^+}]_{\mathrm{out}}^{\mathrm{ranvier0}}$	141.6	$\times$	$\times$	$\times$	mM
$[\mathrm{K^+}]_{\mathrm{in}}^{\mathrm{ranvier0}}$	140.0	$\times$	$\times$	$\times$	mM
$[\mathrm{K^+}]_{\mathrm{out}}^{\mathrm{ranvier0}}$	4.8	$\times$	$\times$	$\times$	mM

section	Parameter Name	OurModel	Mainen95	Mainen96	Hu2009	units
dend11[22]						
	$\bar{g}_{\mathrm{Na_V \cdot Total}}^{\mathrm{dend11[22]}}$	2.51×10^{-3}	0.003	0.00015	8.0×10^{-3}	$\dfrac{\mho}{\mathrm{cm}^2}$
	$\bar{g}_{\mathrm{Na_V \cdot Total}}^{\mathrm{dend11[22]}} \times Q_{\bar{g}_V}^{\mathrm{Mainen}}$	2.51×10^{-3}	3.00×10^{-3}	4.82×10^{-3}	2.57×10^{-2}	$\dfrac{\mho}{\mathrm{cm}^2}$
	$\bar{g}_{\mathrm{K_V}}^{\mathrm{dend11[22]}}$	7.53×10^{-4}	0.01	$\times$	1.0×10^{-3}	$\dfrac{\mho}{\mathrm{cm}^2}$
	$\bar{g}_{\mathrm{K_V}}^{\mathrm{dend11[22]}} \times Q_{\bar{g}_V}^{\mathrm{Mainen}}$	7.53×10^{-4}	1.00×10^{-2}	$\times$	3.21×10^{-3}	$\dfrac{\mho}{\mathrm{cm}^2}$
	$R_{\mathrm{Passive}}^{\mathrm{dend11[22]}}$	7.16×10^{4}	4.00×10^{4}	3.00×10^{4}	3.00×10^{4}	$\Omega \cdot \mathrm{cm}^2$
	$g_{\mathrm{Passive}}^{\mathrm{dend11[22]}}$	1.40×10^{-5}	2.50×10^{-5}	3.33×10^{-5}	3.33×10^{-5}	$\dfrac{\mho}{\mathrm{cm}^2}$
	$g_{\mathrm{Cl^-, \, leak}}^{\mathrm{dend11[22]}}$	2.09×10^{-6}	$\times$	$\times$	$\times$	$\dfrac{\mho}{\mathrm{cm}^2}$
	$g_{\mathrm{Na^+, \, leak}}^{\mathrm{dend11[22]}}$	2.23×10^{-6}	$\times$	$\times$	$\times$	$\dfrac{\mho}{\mathrm{cm}^2}$
	$g_{\mathrm{K^+, \, leak}}^{\mathrm{dend11[22]}}$	9.66×10^{-6}	$\times$	$\times$	$\times$	$\dfrac{\mho}{\mathrm{cm}^2}$
	$I_{\mathrm{MaxPump}}^{\mathrm{dend11[22]}}$	1.33×10^{-3}	$\times$	$\times$	$\times$	$\dfrac{\mathrm{mA}}{\mathrm{cm}^2}$
	$V_{\mathrm{m}}^{\mathrm{dend11[22]}}$	-70.0	-70.0	-70.0	-70.0	mV
	$E_{\mathrm{leak}}^{\mathrm{dend11[22]}}$	$\times$	-70.0	-70.0	-70.0	mV

$E_{\mathrm{Cl}}^{\mathrm{dend11[22]}}$	-70.0	$\times$	$\times$	$\times$	mV
$E_{\mathrm{Na}}^{\mathrm{dend11[22]}}$	60.0	60.0	50.0	60.0	mV
$E_{\mathrm{K}}^{\mathrm{dend11[22]}}$	-90.0	-90.0	-90.0	-90.0	mV
$[\mathrm{Cl}^-]_{\mathrm{in}}^{\mathrm{dend11[22]}}$	11.0	$\times$	$\times$	$\times$	mM
$[\mathrm{Cl}^-]_{\mathrm{out}}^{\mathrm{dend11[22]}}$	151.0	$\times$	$\times$	$\times$	mM
$[\mathrm{Na}^+]_{\mathrm{in}}^{\mathrm{dend11[22]}}$	15.0	$\times$	$\times$	$\times$	mM
$[\mathrm{Na}^+]_{\mathrm{out}}^{\mathrm{dend11[22]}}$	141.6	$\times$	$\times$	$\times$	mM
$[\mathrm{K}^+]_{\mathrm{in}}^{\mathrm{dend11[22]}}$	140.0	$\times$	$\times$	$\times$	mM
$[\mathrm{K}^+]_{\mathrm{out}}^{\mathrm{dend11[22]}}$	4.8	$\times$	$\times$	$\times$	mM